

High-field termination of a Cooper-pair insulator

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*Localization, Interaction, and Superconductivity
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Idan Tamir



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Johanna Seidemann



Claude Chapelier



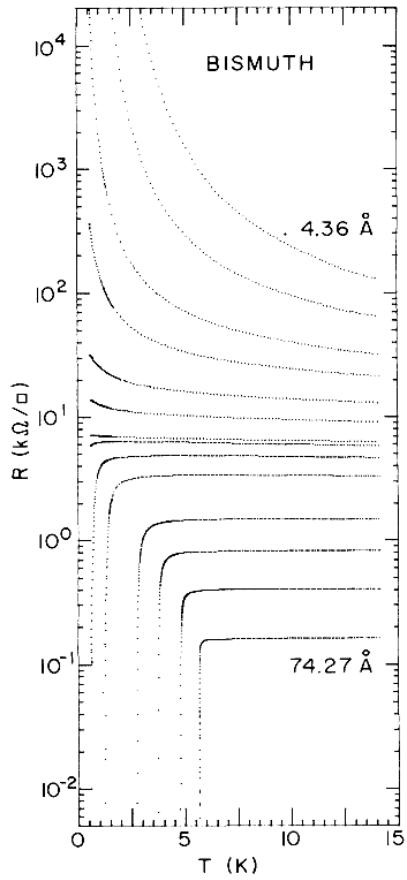
Benjamin Piot



Our playground: thin superconducting films

Superconductor-to-insulator quantum phase transition (SIT)

Quench condensed Bismuth films



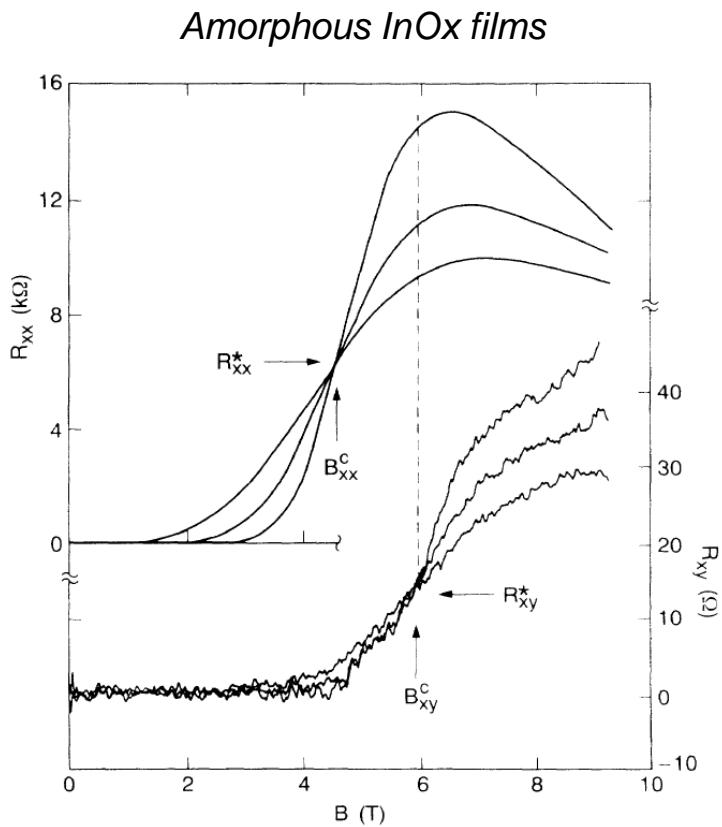
Measure of disorder: sheet resistance

$$R_{\square} = \frac{\rho}{d}$$

Resistivity
Thickness

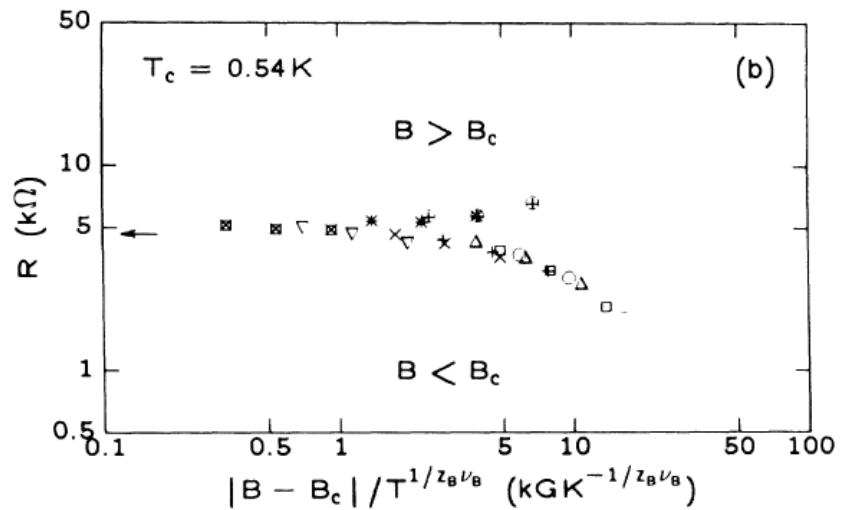
Our playground: thin superconducting films

B-tuned SIT



Finite size scaling

$$\frac{R}{R_c} = f\left(\frac{|B - B_c|}{T_z v}\right)$$



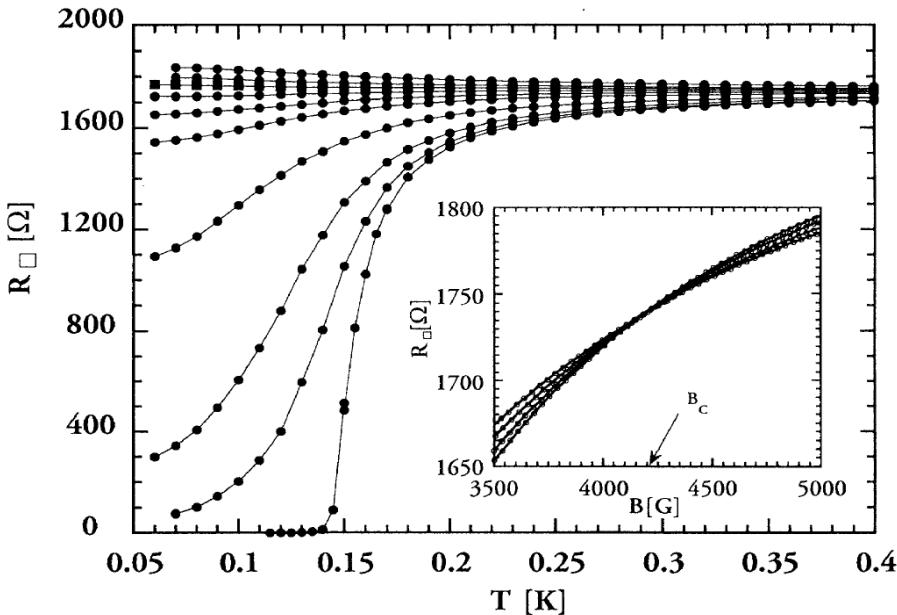
M. Paalanen, A. Hebard, R. Ruel, *PRL* ('92)

A. Hebard, M. Paalanen, *PRL* ('90)

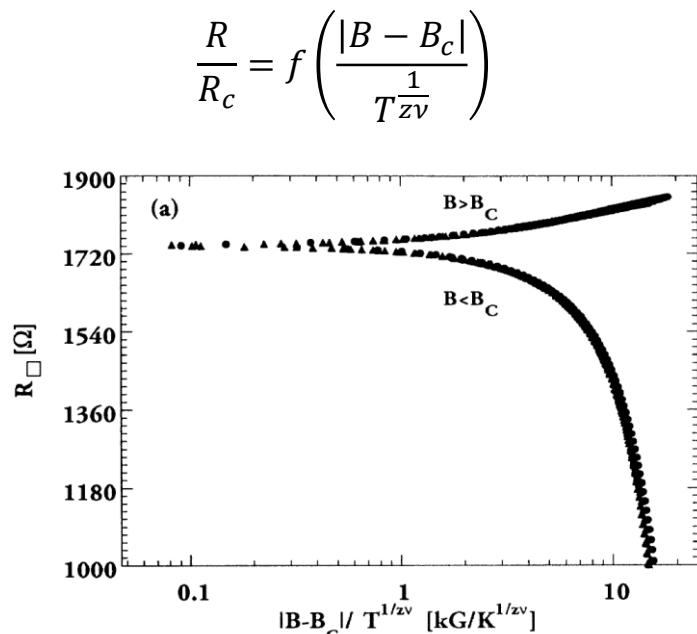
Our playground: thin superconducting films

B-tuned SIT

Amorphous MoGe films



Finite size scaling



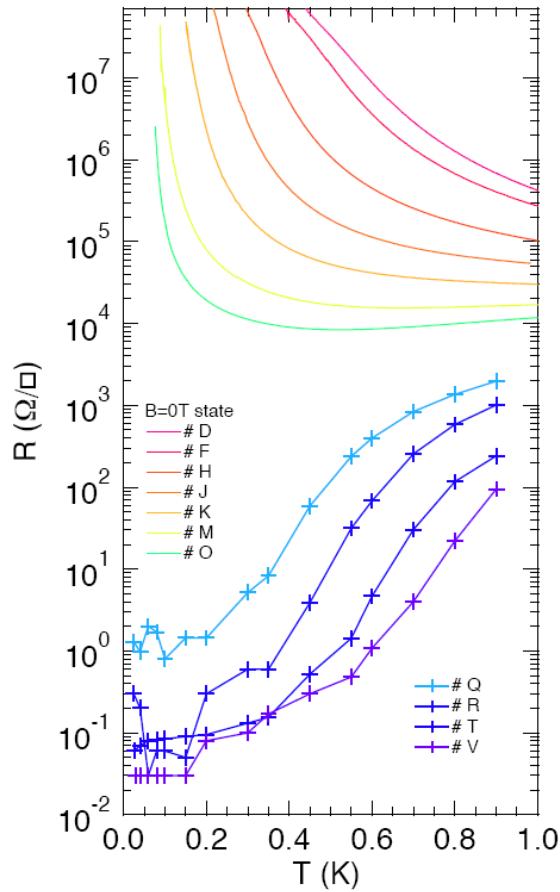
A. Yazdani & A. Kapitulnik *PRL* ('95)

(Critical exponents on different materials: $0.7 < zv < 2.3$)

Direct superconductor-insulator transition

Amorphous indium oxide films

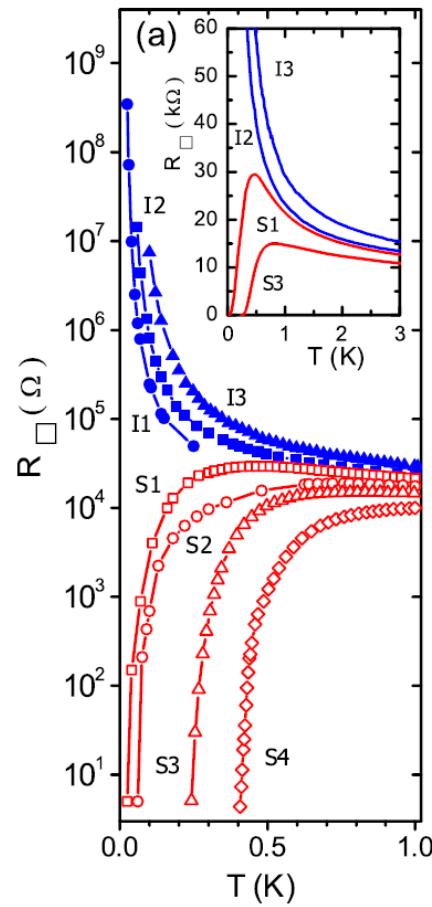
D. Shahar's group



$$n \lesssim 10^{21} \text{ cm}^{-3}$$

Titanium nitride

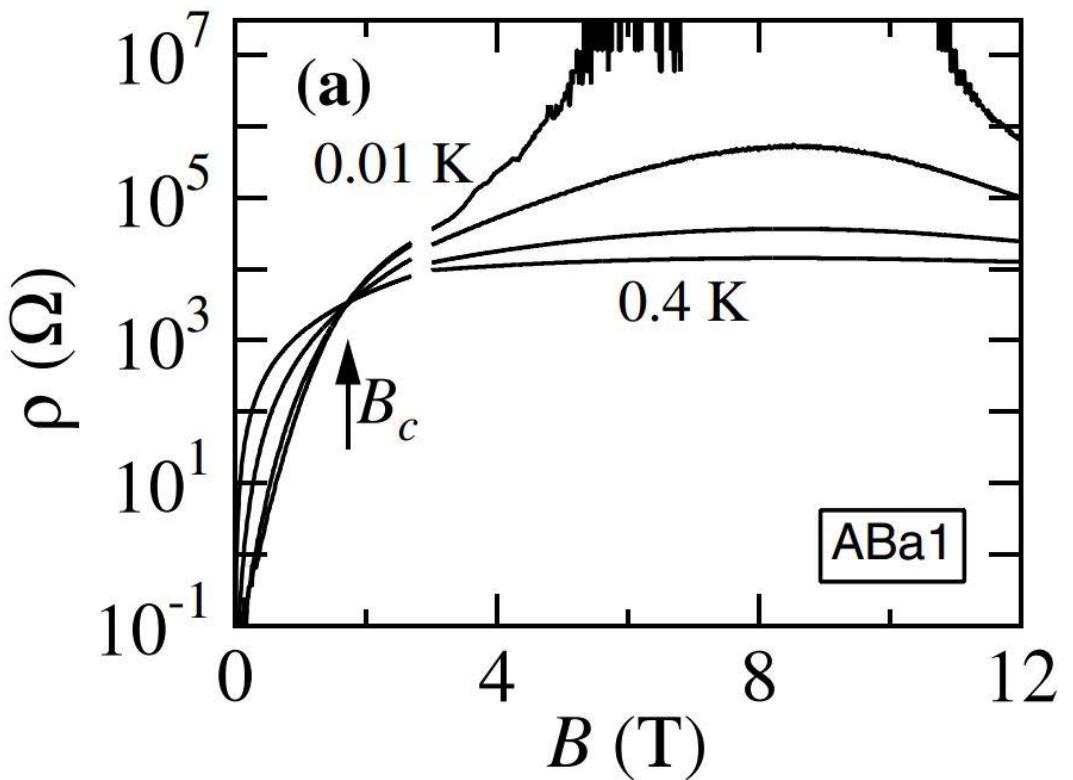
T. Baturina PRLs ('07)



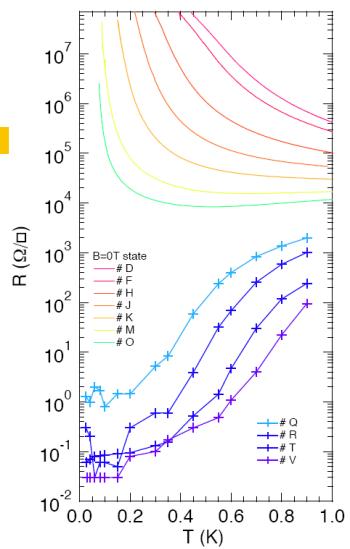
$$n \sim 10^{22} \text{ cm}^{-3}$$

Direct superconductor-insulator transition

B-induced transition: Giant magneto-resistance peak

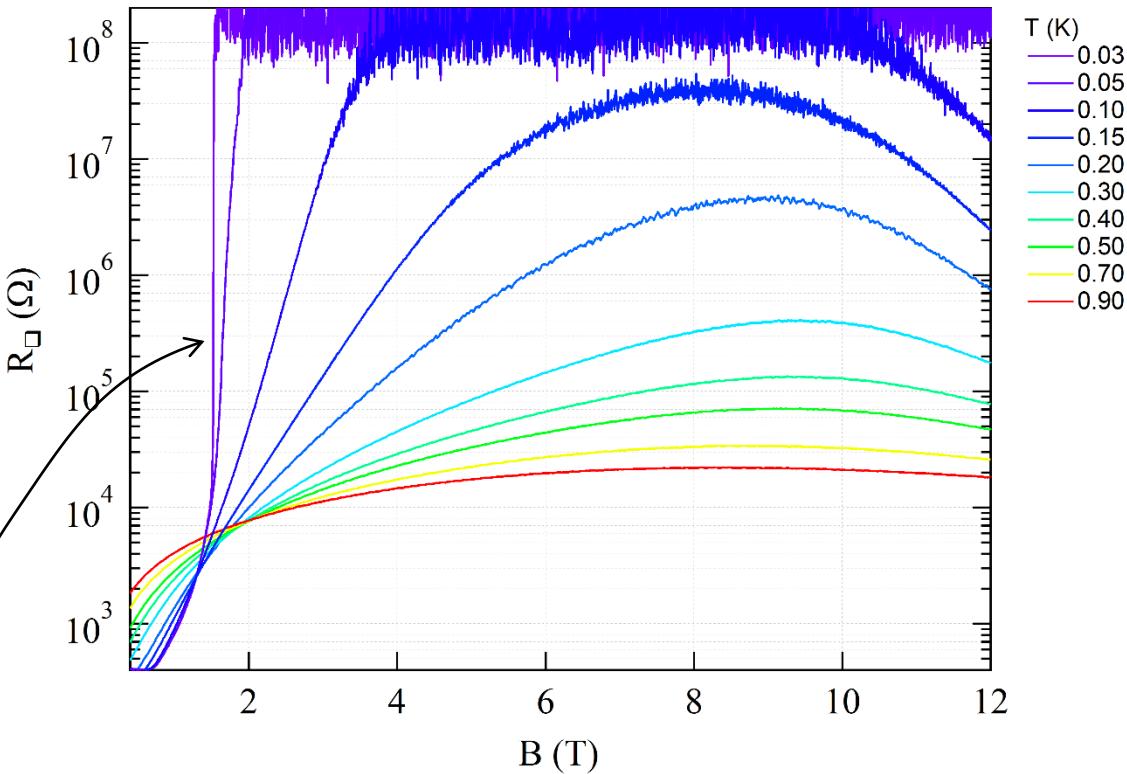


Sambandamurthy et. al. *PRL* ('05)

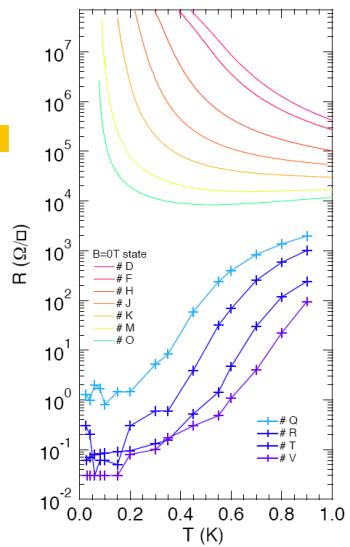


Direct superconductor-insulator transition

B-induced transition: Giant magneto-resistance peak



R raises by 1 decade per 0.01 tesla



Cooper-pair insulator

PRL 103, 157001 (2009)

PHYSICAL REVIEW LETTERS

week ending
9 OCTOBER 2009

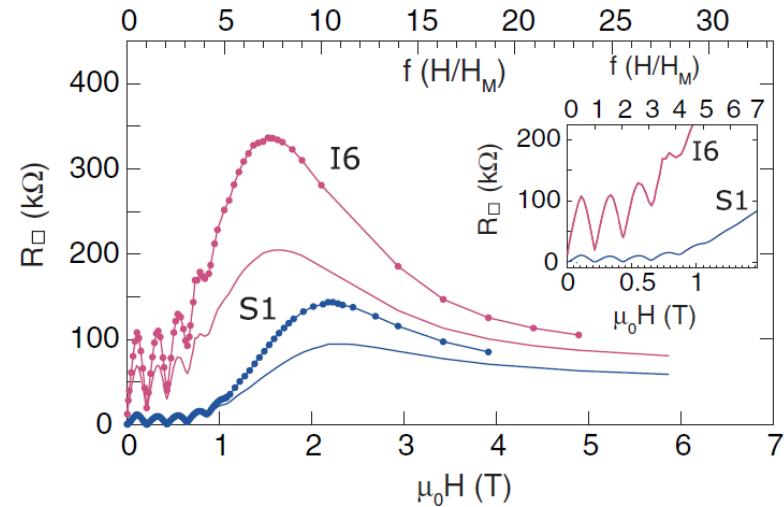
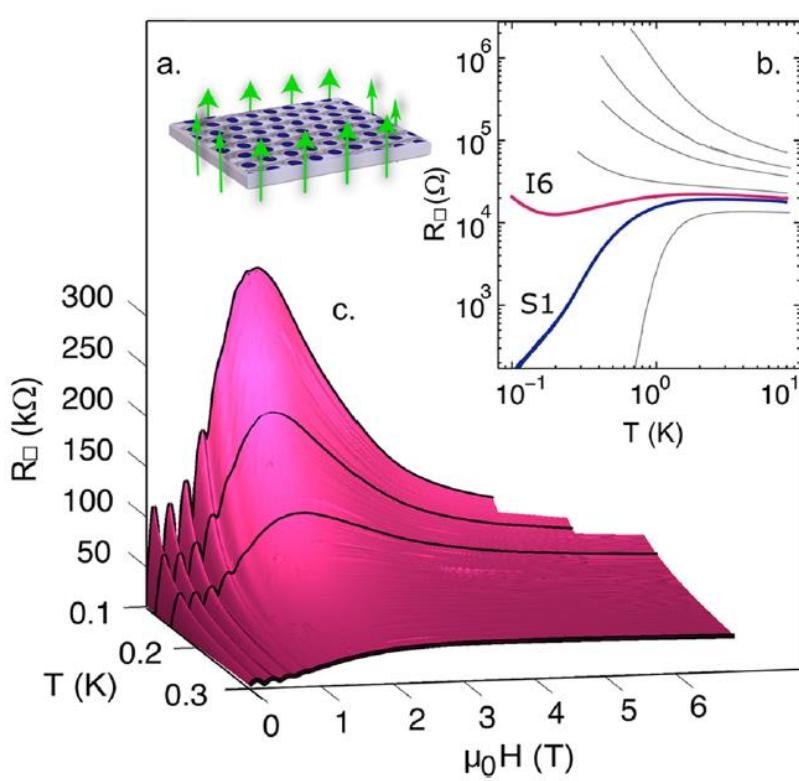
Observation of Giant Positive Magnetoresistance in a Cooper Pair Insulator

H. Q. Nguyen,¹ S. M. Hollen,¹ M. D. Stewart, Jr.,¹ J. Shainline,¹ Aijun Yin,² J. M. Xu,² and J. M. Valles, Jr.¹

¹Department of Physics, Brown University, Providence, Rhode Island 02912, USA

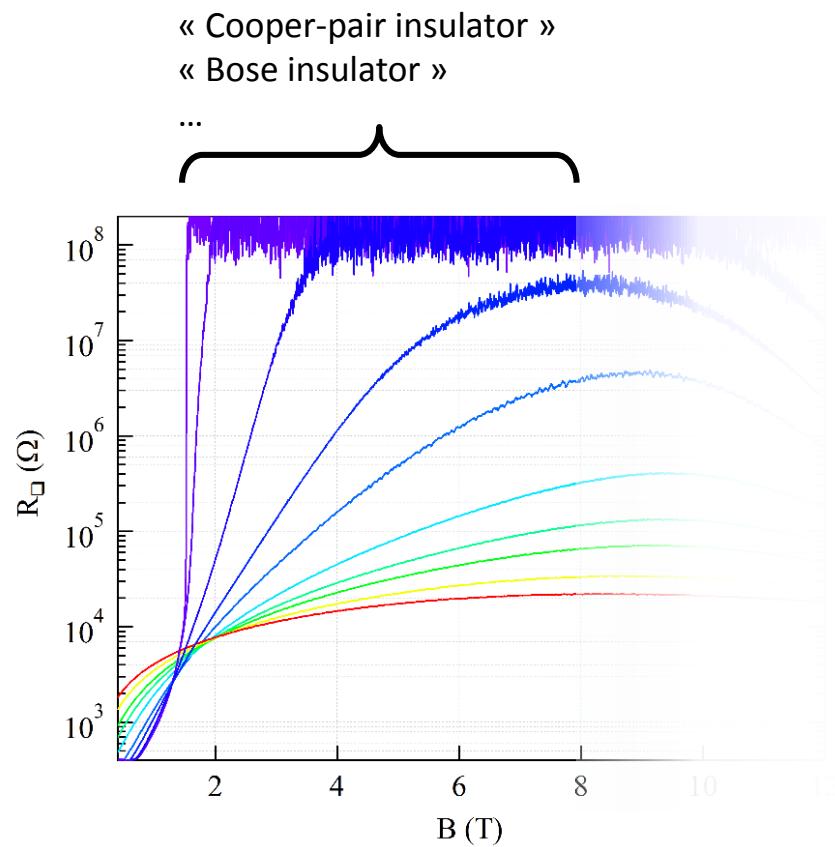
²Division of Engineering, Brown University, Providence, Rhode Island 02912, USA

(Received 23 July 2009; revised manuscript received 18 September 2009; published 5 October 2009)

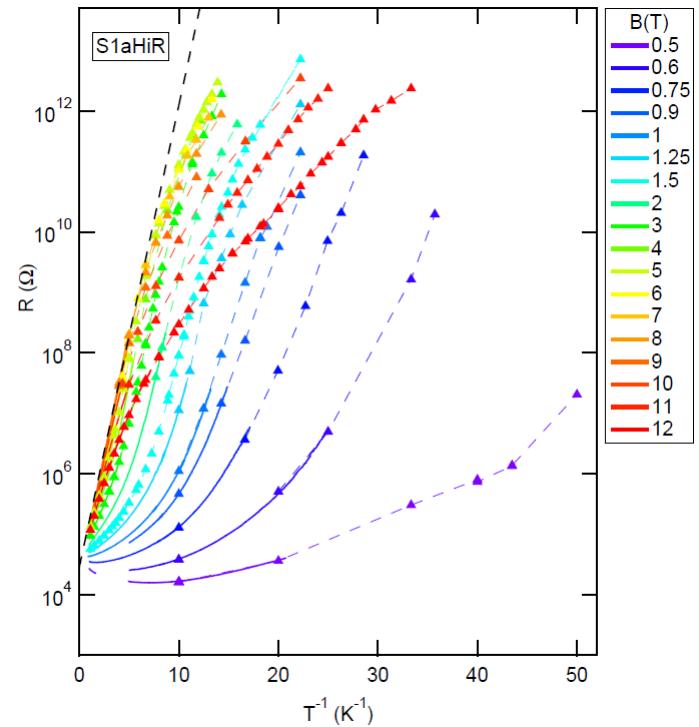
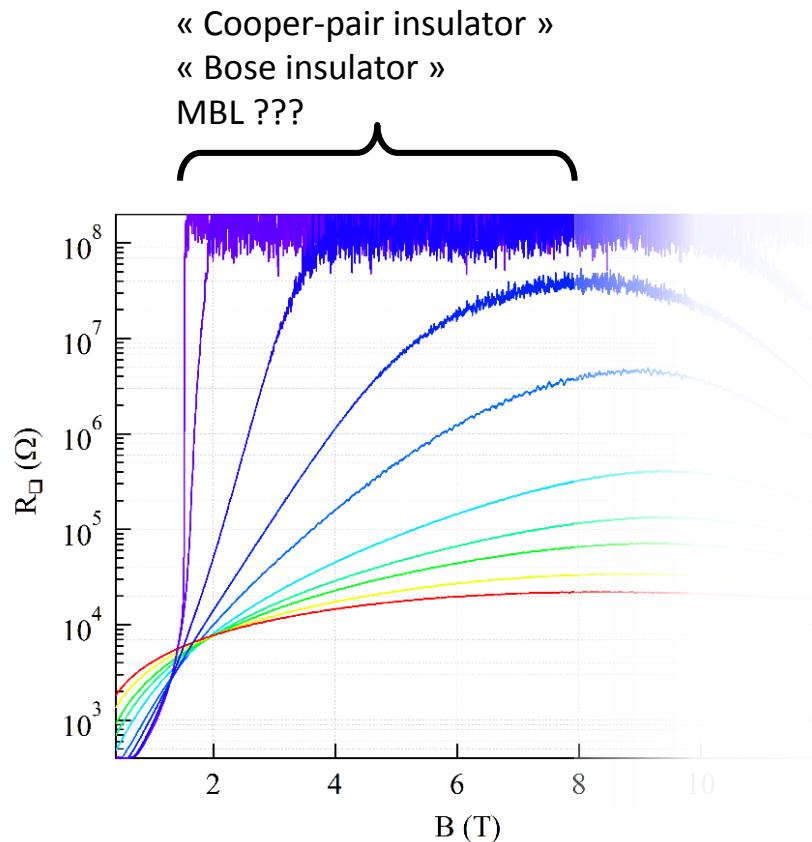


J. Valles group, *Science* ('07), *PRL* ('09)
D. Shahar group, *PRL* ('12)

B-tuned superconductor-insulator transition



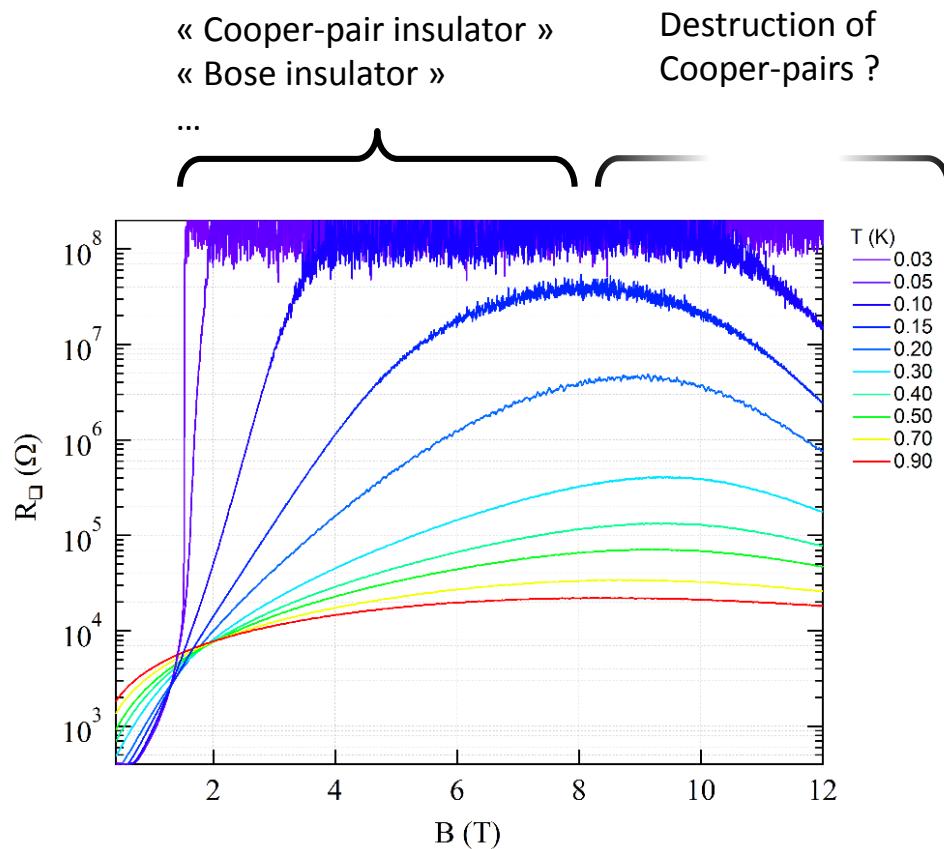
B-tuned superconductor-insulator transition



Cooper-pair insulator: R diverges faster than activation

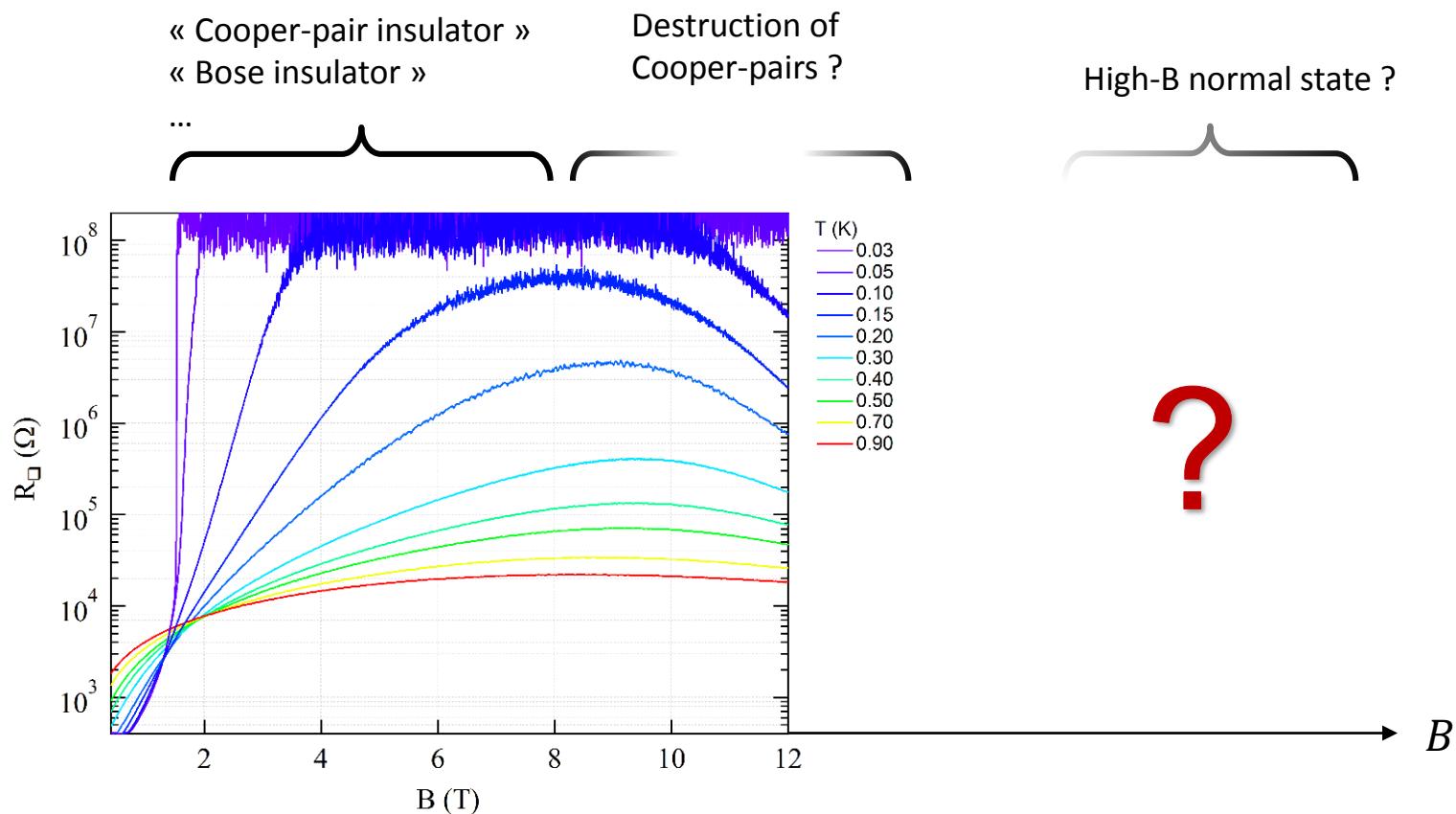
See Idan Tamir talk: « A finite temperature insulator ? »

B-tuned superconductor-insulator transition



Q1: Does Cooper pairing survive up to 12 T ?

B-tuned superconductor-insulator transition

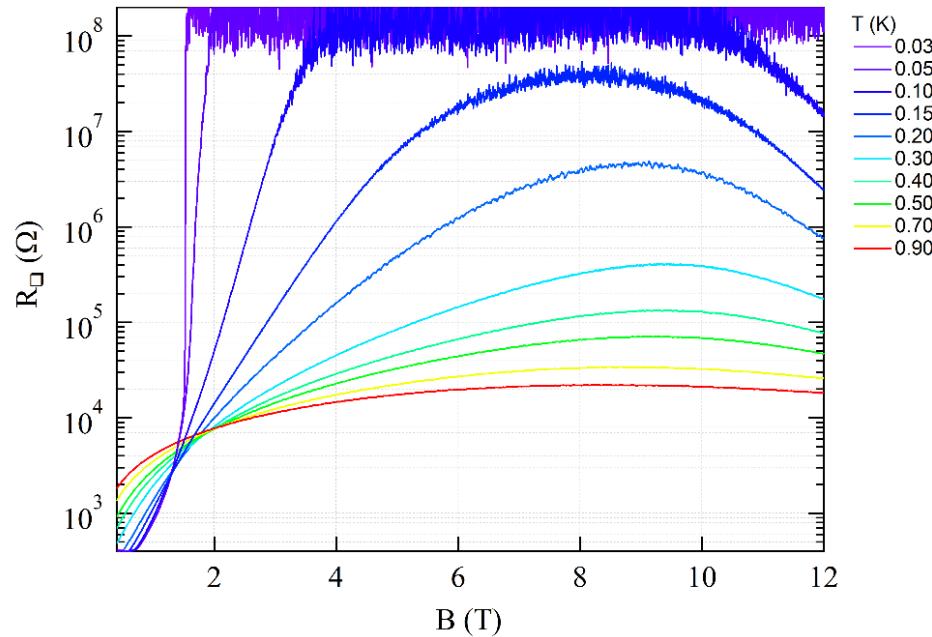


Q1: Does Cooper pairing survive up to 12 T ?

Q2: What's the high-B normal state ?

B-tuned superconductor-insulator transition

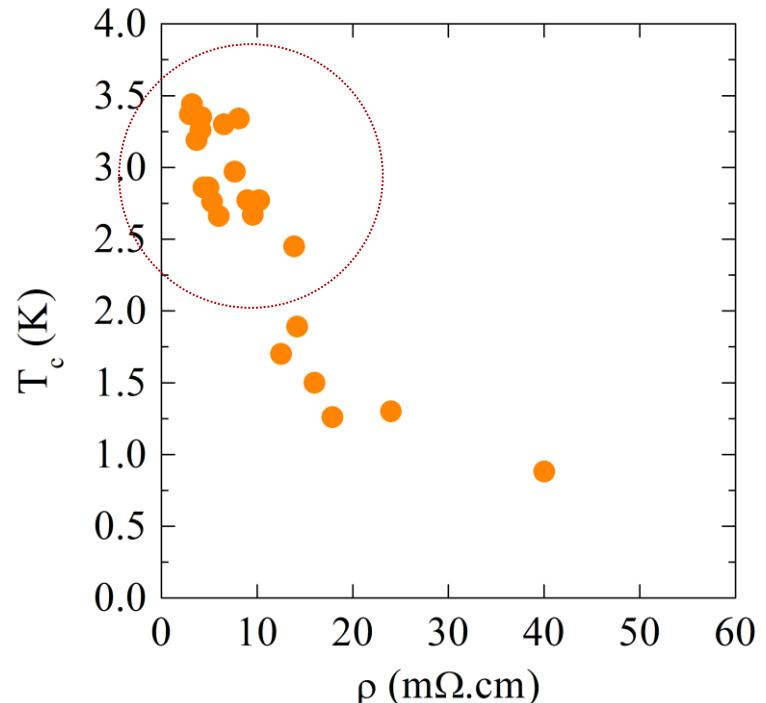
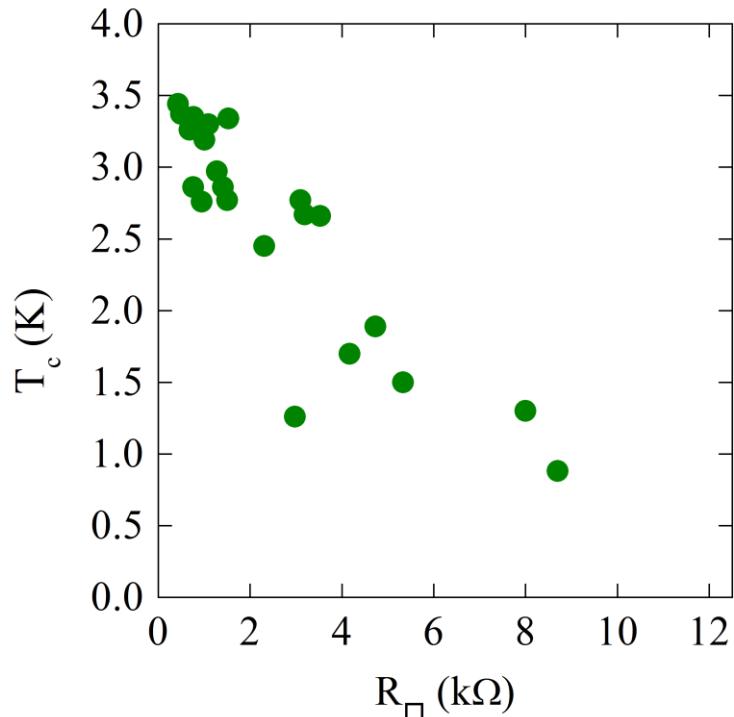
Q1: Does Cooper pairing survive up to 12 T ?



Low disorder InOx films far from SIT

« Low disorder » amorphous InOx films

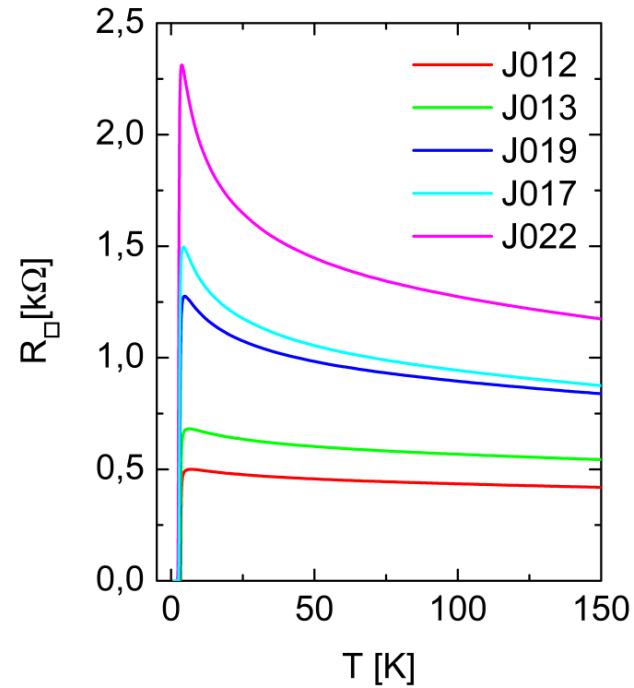
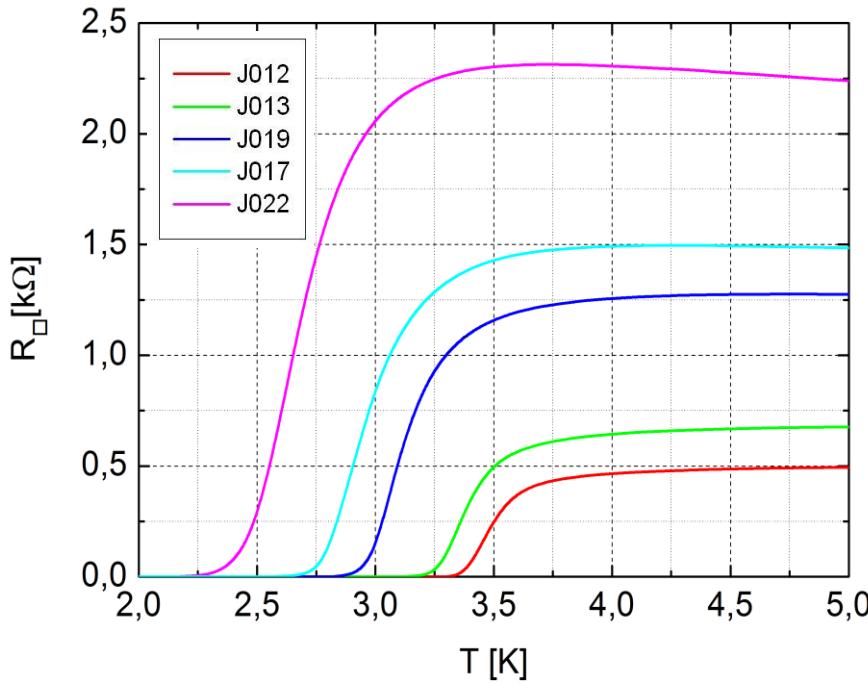
- E-gun evaporation of In_2O_3 on SiO_2 under O_2 pressure
- 60 nm thick
- $k_F l_e < 1$
- $T_c \geq 2K$



Low disorder InOx films far from SIT

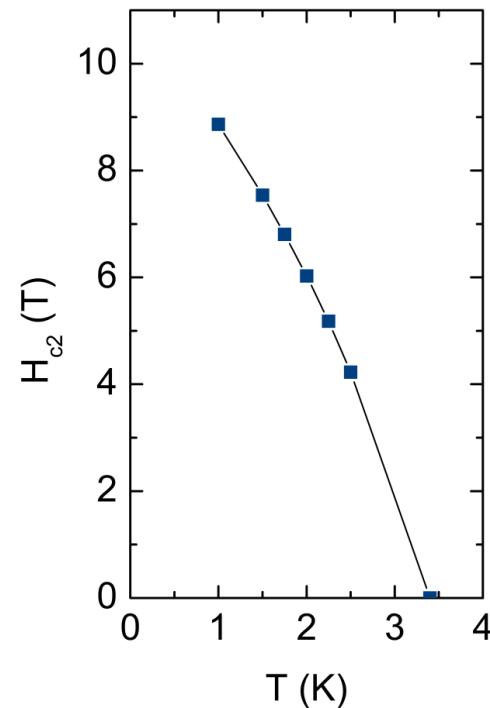
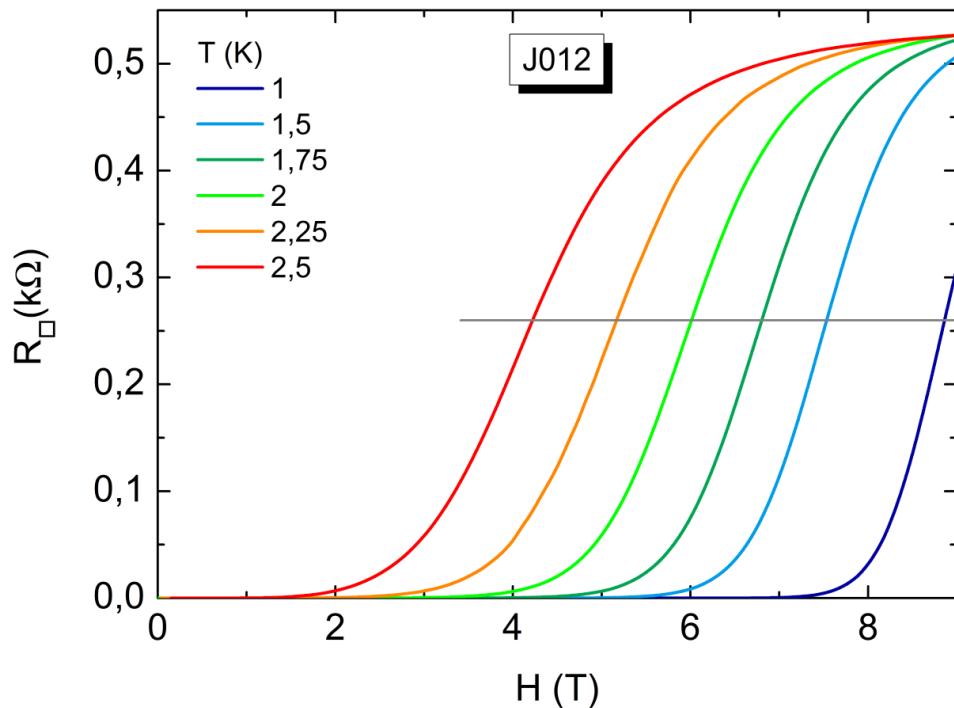
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Low disorder InOx films

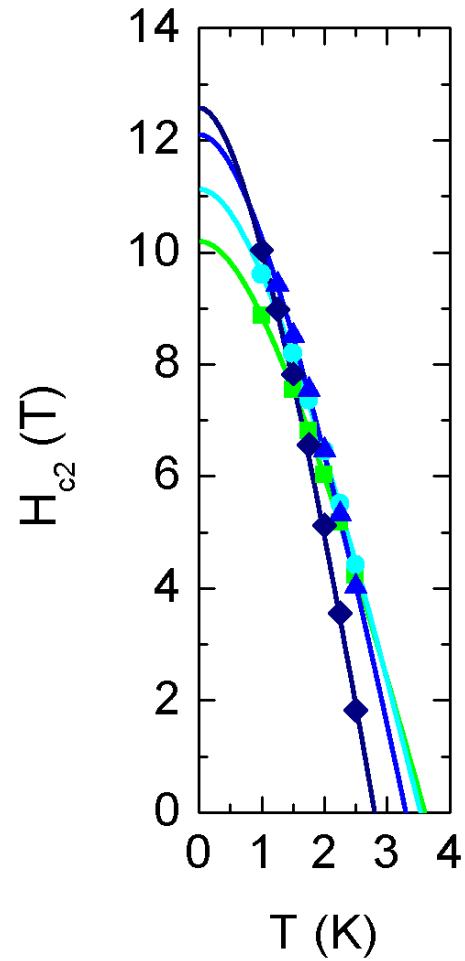
Magneto-resistance isotherm



→ *Usual behavior for dirty superconductors*

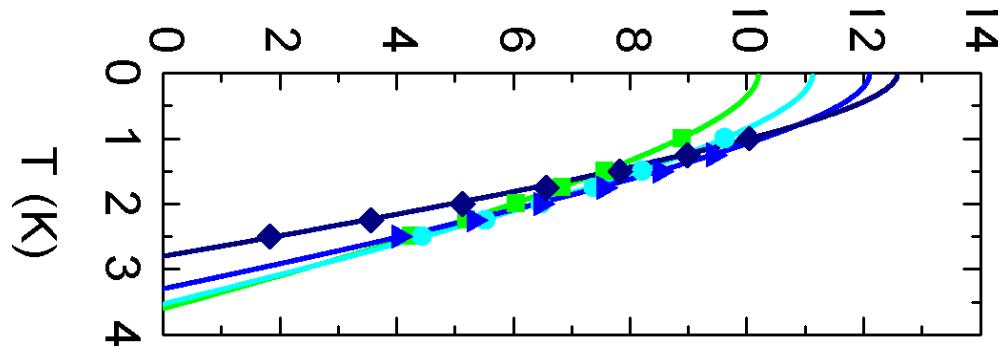
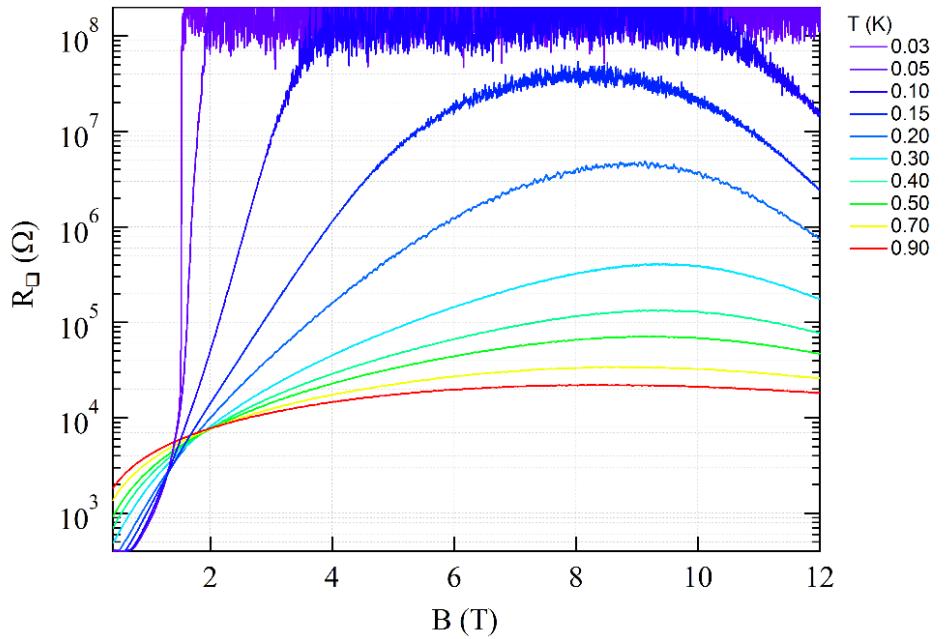
Low disorder InOx films

Q1: Does Cooper pairing survive up to 12 T ? **YES**

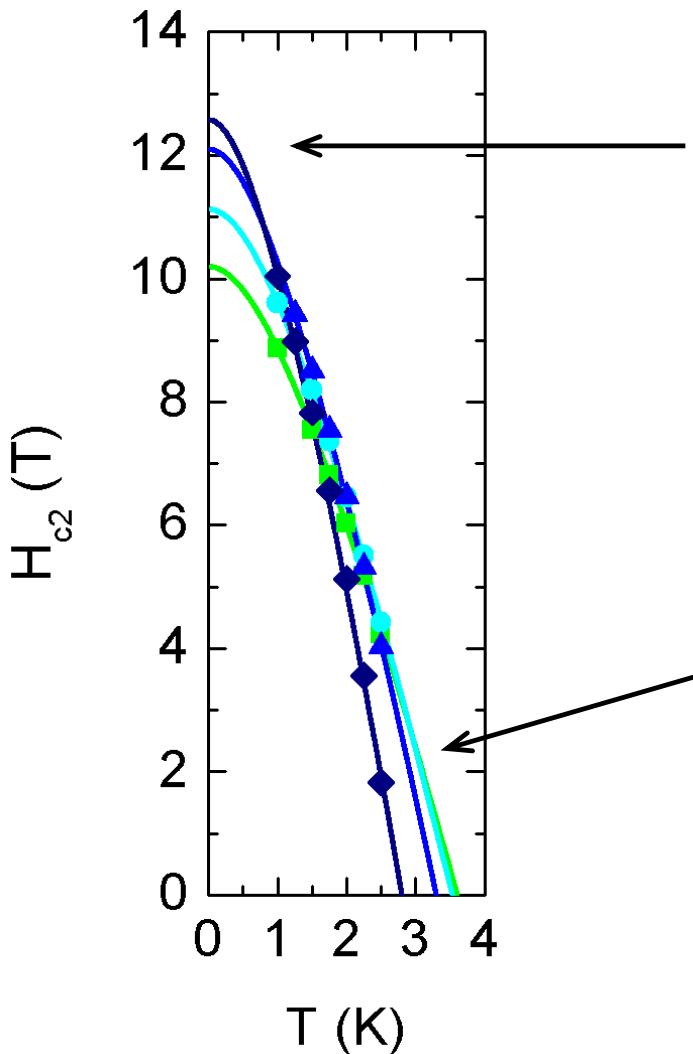


InOx films far from SIT

Q1: Does Cooper pairing survive up to 12 T ? **YES**



Superconducting parameters



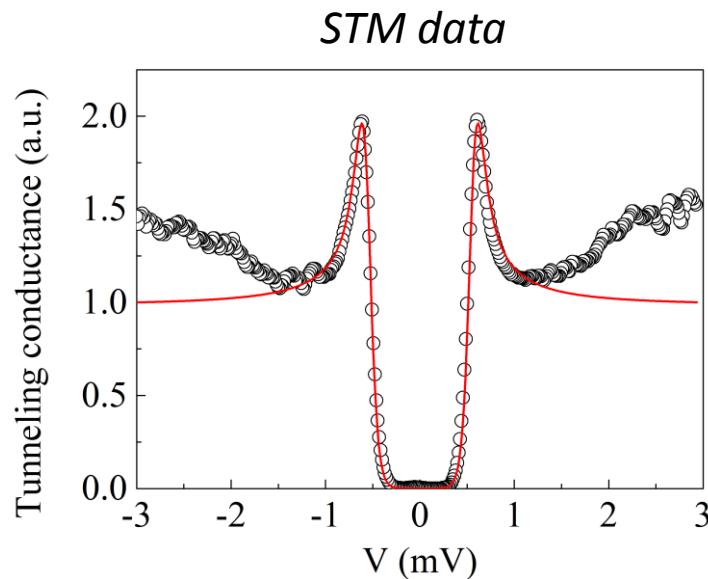
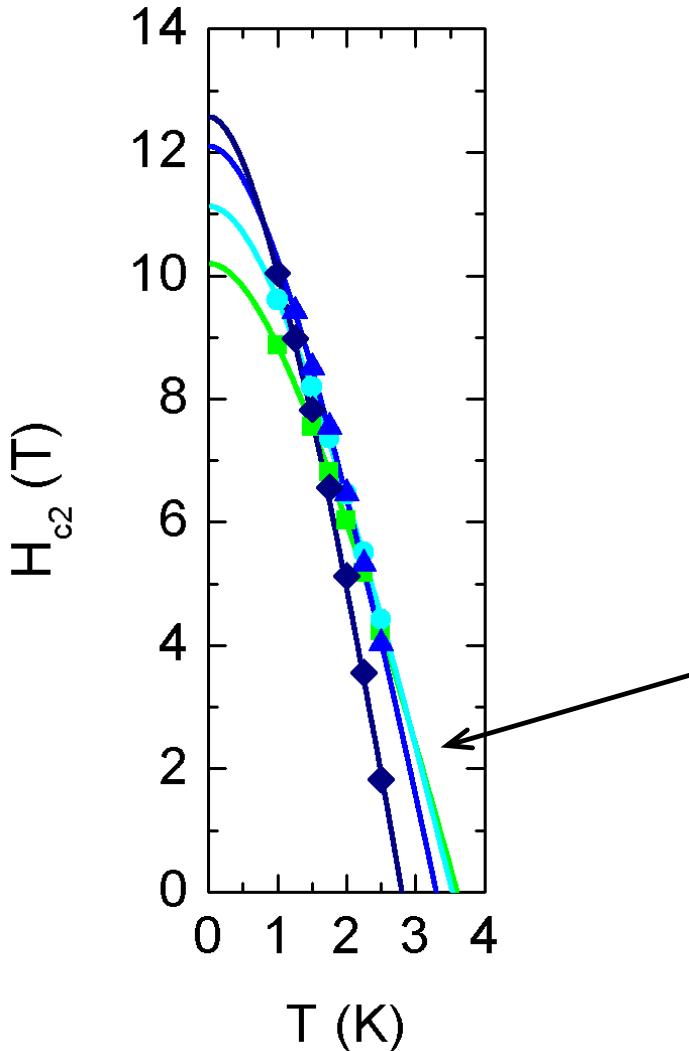
Superconducting coherence length

$$H_{c2}(0) \Rightarrow \xi_d \approx 4.0 - 4.7 \text{ nm}$$

Diffusion coefficient

$$\frac{dH_{c2}}{dT} \propto -\frac{1}{D} \Rightarrow D \approx 0.18 - 0.28 \text{ cm}^2/\text{s}$$

Superconducting parameters



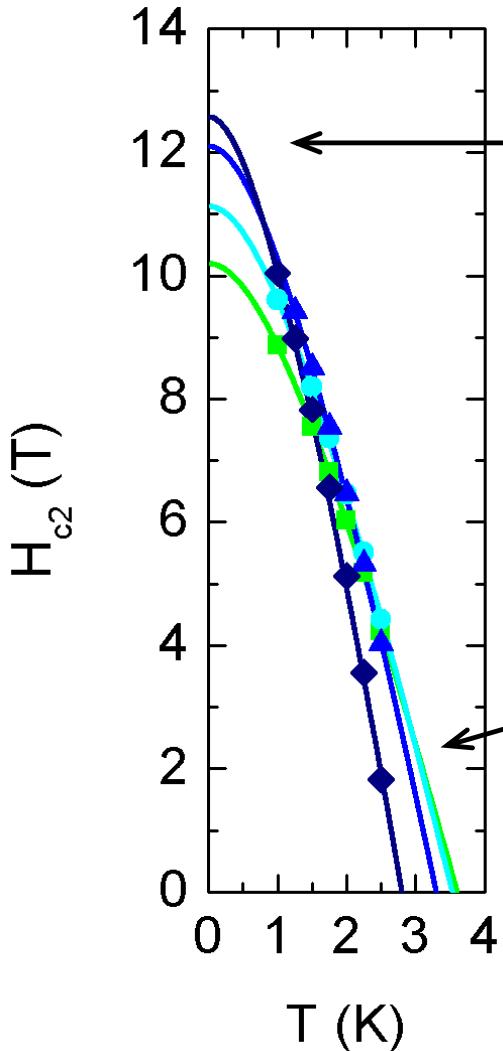
Diffusion coefficient

$$\frac{dH_{c2}}{dT} \propto -\frac{1}{D} \quad \Rightarrow \quad D \approx 0.18 - 0.28 \text{ cm}^2/\text{s}$$

Superconducting gap (STM data)

$$\Delta = 550 \mu eV \quad \Rightarrow \quad \xi_d = 0.83 \sqrt{\frac{\hbar D}{\Delta}} \approx 4 \text{ nm}$$

Superconducting parameters



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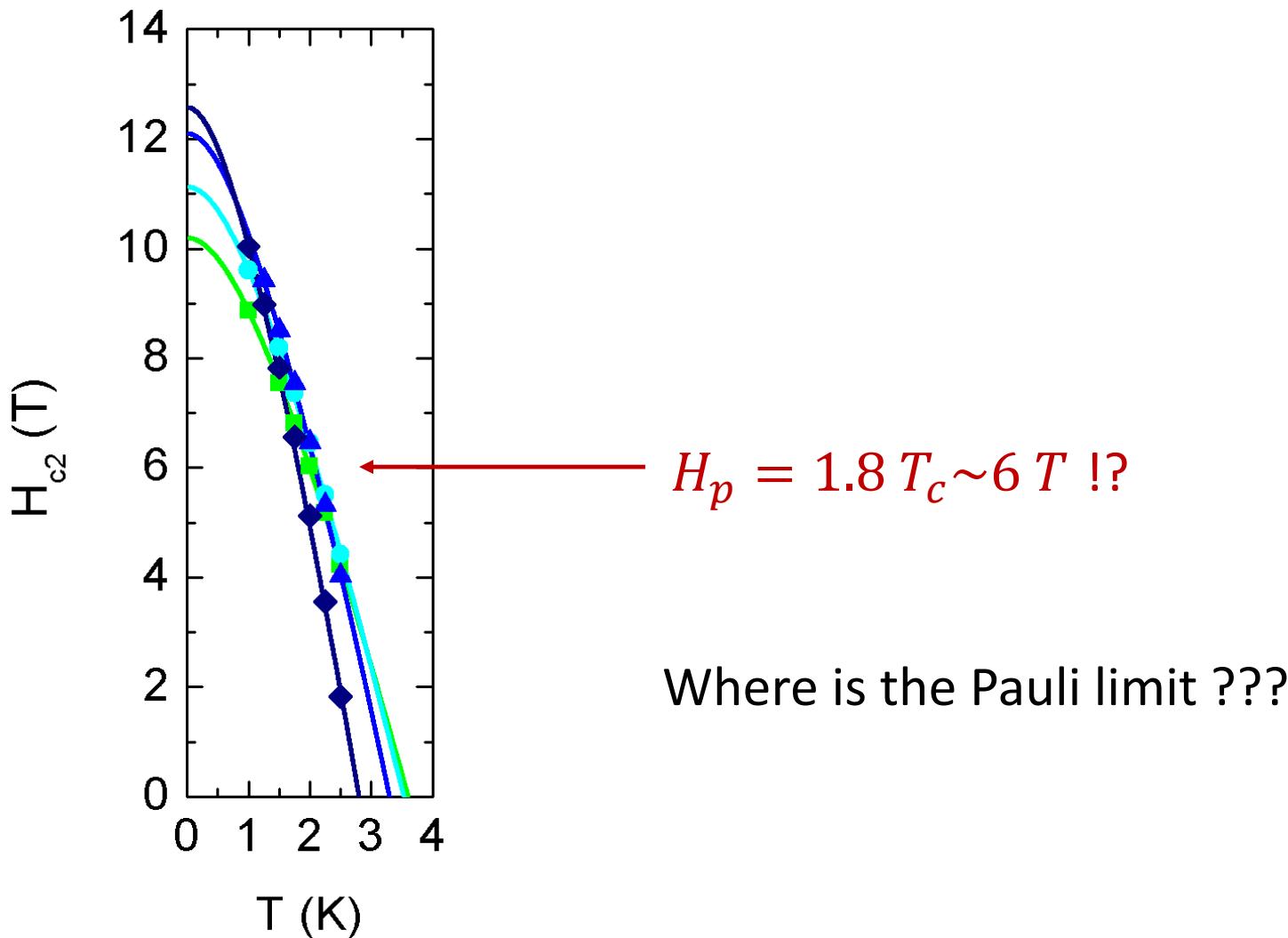
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Superconducting gap (STM data)

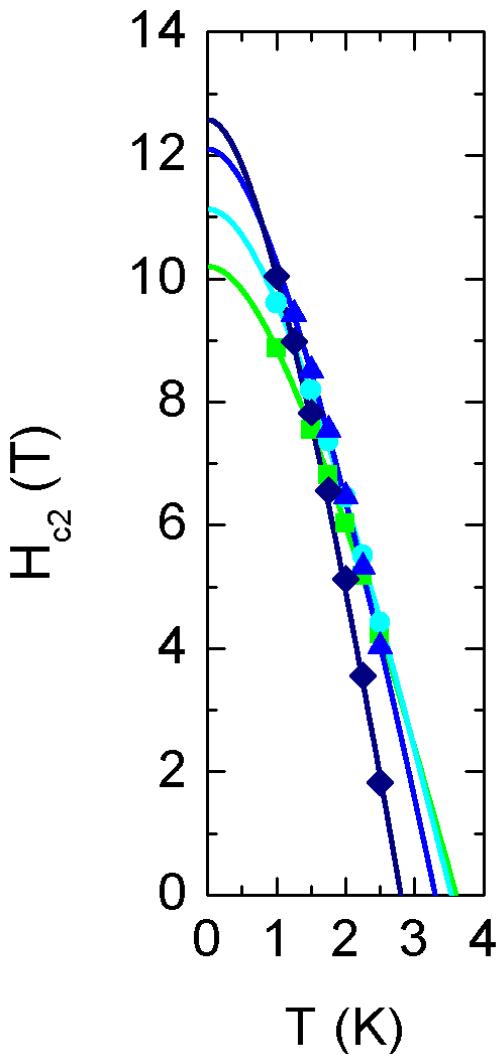
$$\Delta = 550 \mu eV \Rightarrow \xi_d = 0.83 \sqrt{\frac{\hbar D}{\Delta}} \approx 4 \text{ nm}$$

→ *Superconductivity is not quasi 2D in InOx*

Superconducting parameters



Absence of Pauli limit due to spin-orbit scattering on In atoms



Estimate of the Pauli field with spin-orbit scattering

$$\chi_S/\chi_N \simeq 1 - 2 \Delta \tau_{so}/\hbar \quad \text{for} \quad \Delta \ll \hbar/\tau_{so}$$

$$\Rightarrow B_p \propto \frac{1}{\mu_B} \frac{\Delta}{\sqrt{\Delta \tau_{so}/\hbar}}$$

Anderson PRL ('59)
Clogston PRL ('62)
Feigelman private comm.

Estimate of τ_{so} in InOx

$$\tau_{so} = \frac{\tau}{(Z\alpha)^4} \sim 60 \cdot \tau$$

$$\alpha \simeq 1/137$$

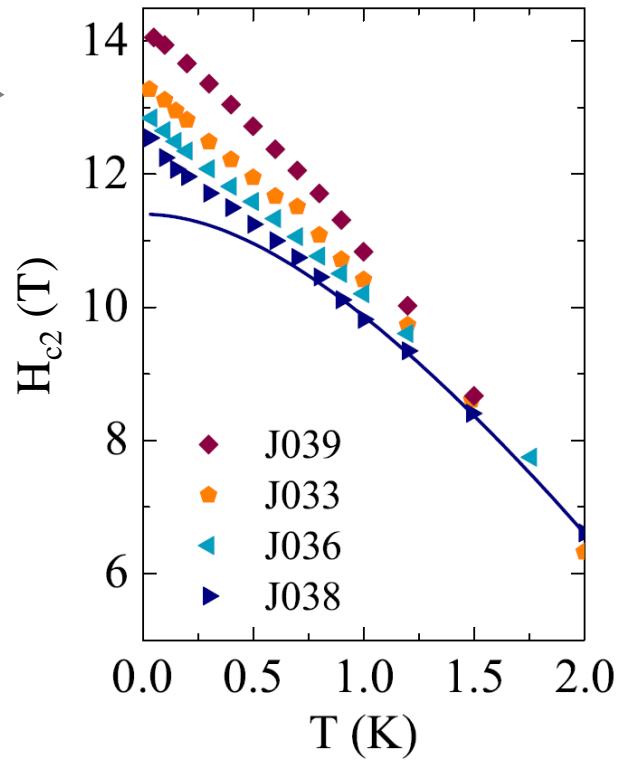
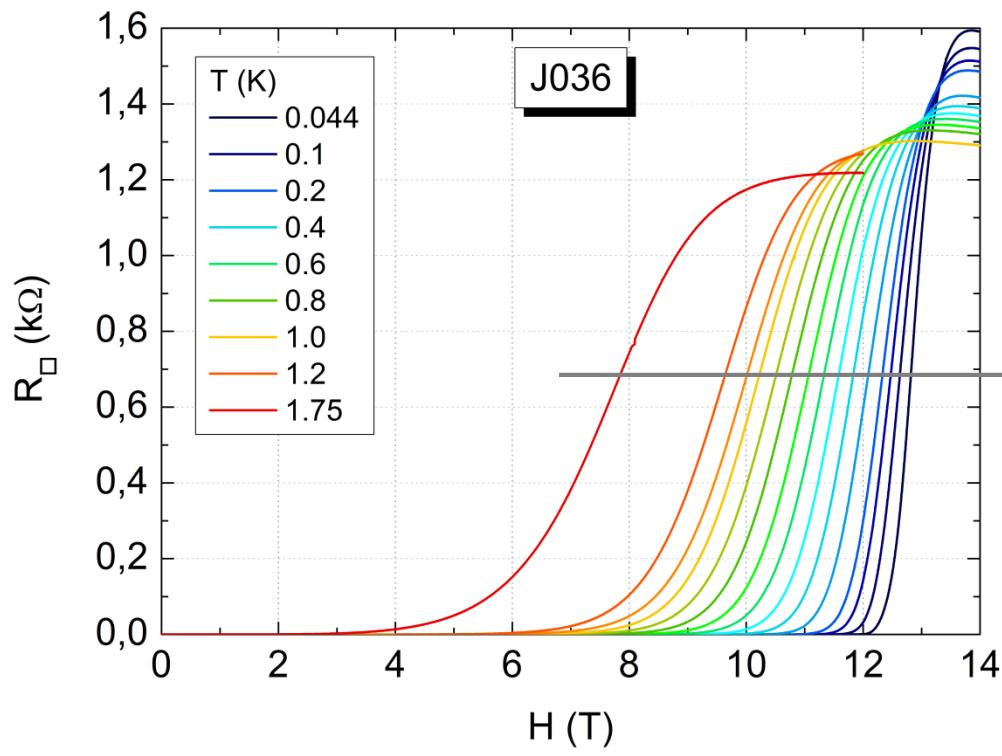
Abrikosov, Gor'kov ('62)

$$\text{With } \tau \sim 3 \cdot 10^{-16} \text{ s} \Rightarrow \tau_{so} \sim 2 \cdot 10^{-14} \text{ s}$$

$$\Rightarrow \frac{1}{\sqrt{\Delta \tau_{so}/\hbar}} \sim 10$$

H_{c2} is limited by orbital effect only

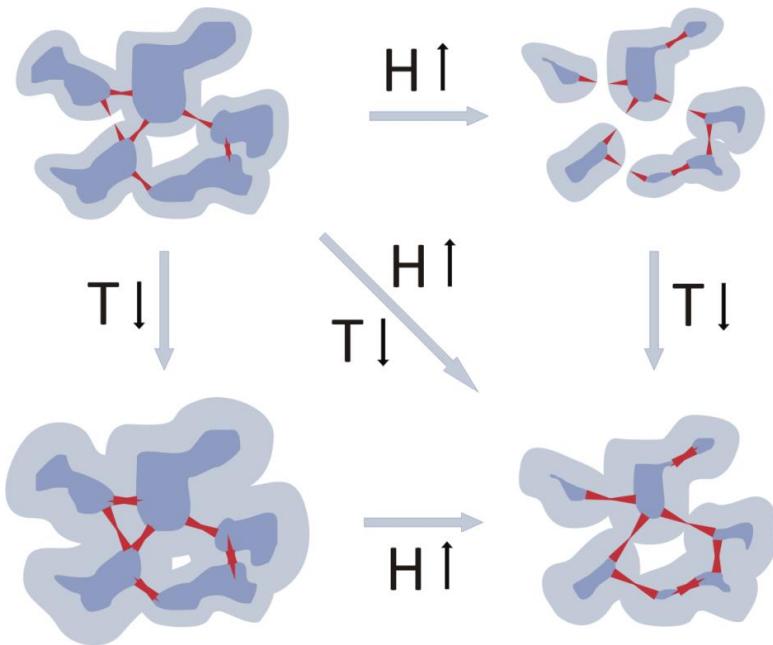
Films far from SIT



Deviation from BCS behavior at low T

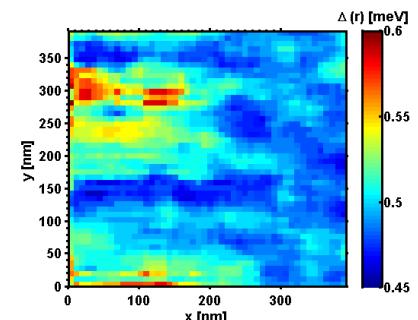
Mesoscopic fluctuations near $H_c2(0)$

Galitski and Larkin, *PRL* ('01)

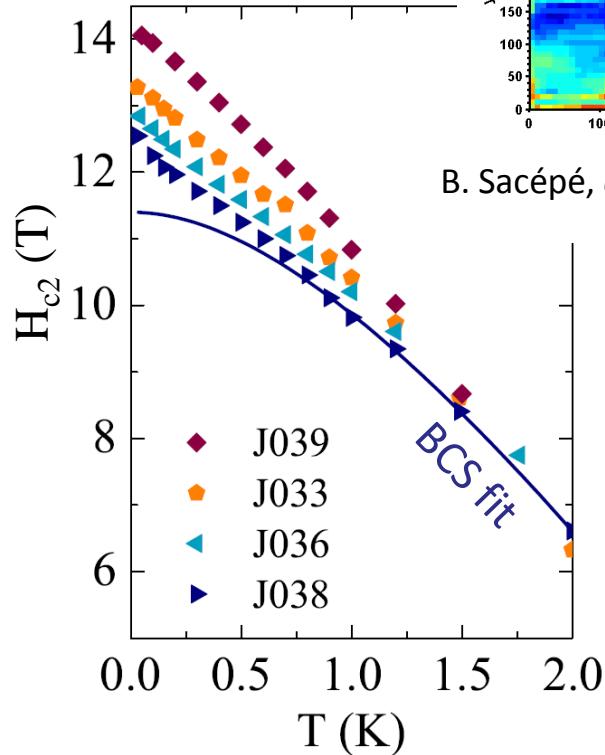


- $B \nearrow$: decrease of SC island size
- $T \searrow$: increase of SC proximity effect

STM mapping of $\Delta(r)$

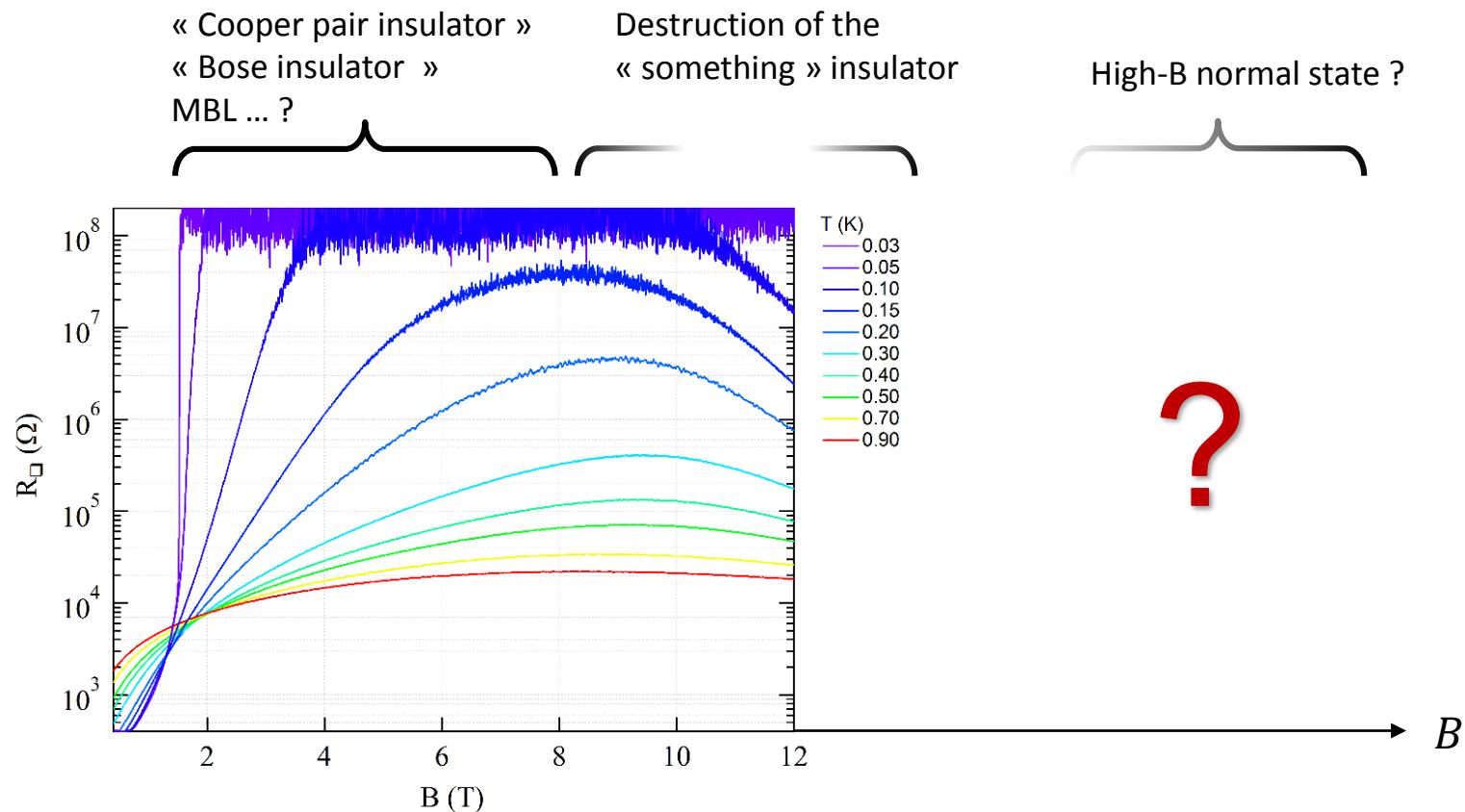


B. Sacépé, et al., *Nat. Phys.* ('11)



See also Hebard and Paalanen, *PRB* ('84)

B-tuned superconductor-insulator transition



Q2: What's the high-B normal state ?

Magneto-resistance measurements

$$0.03K \leq T \leq 2K \quad B \leq 35T$$

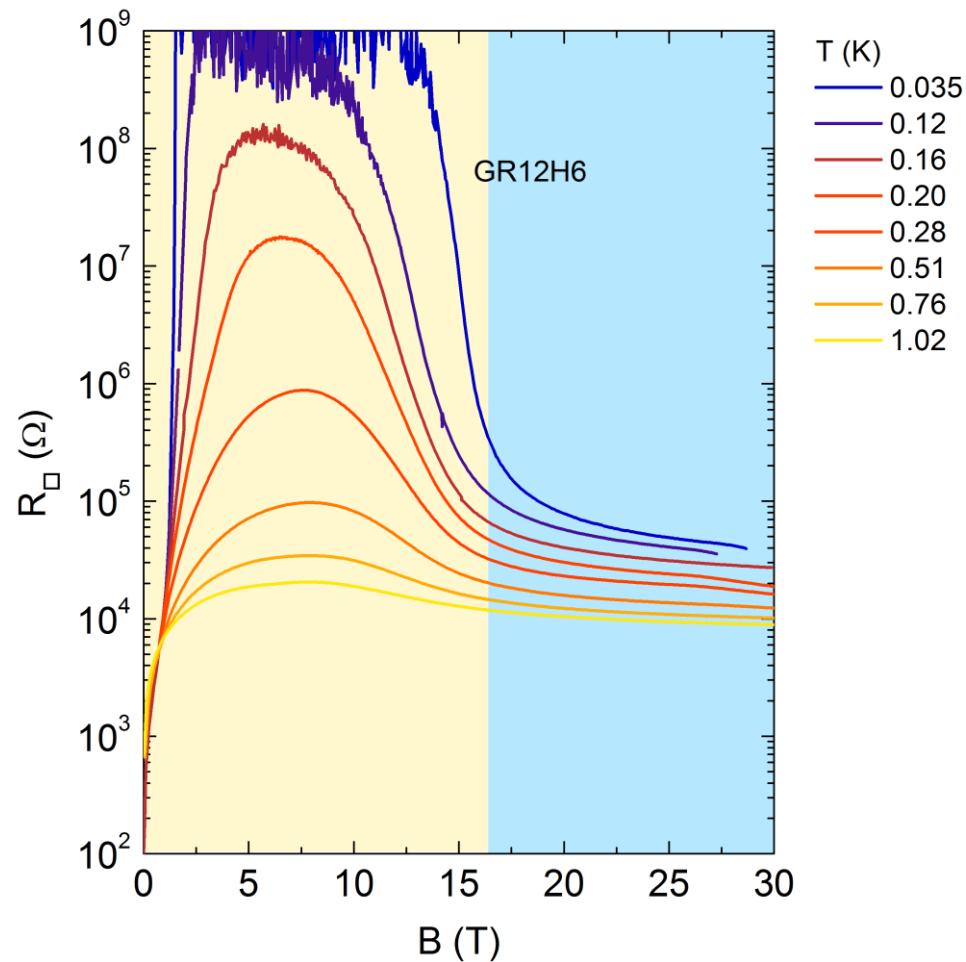
Top-loading dilution fridge



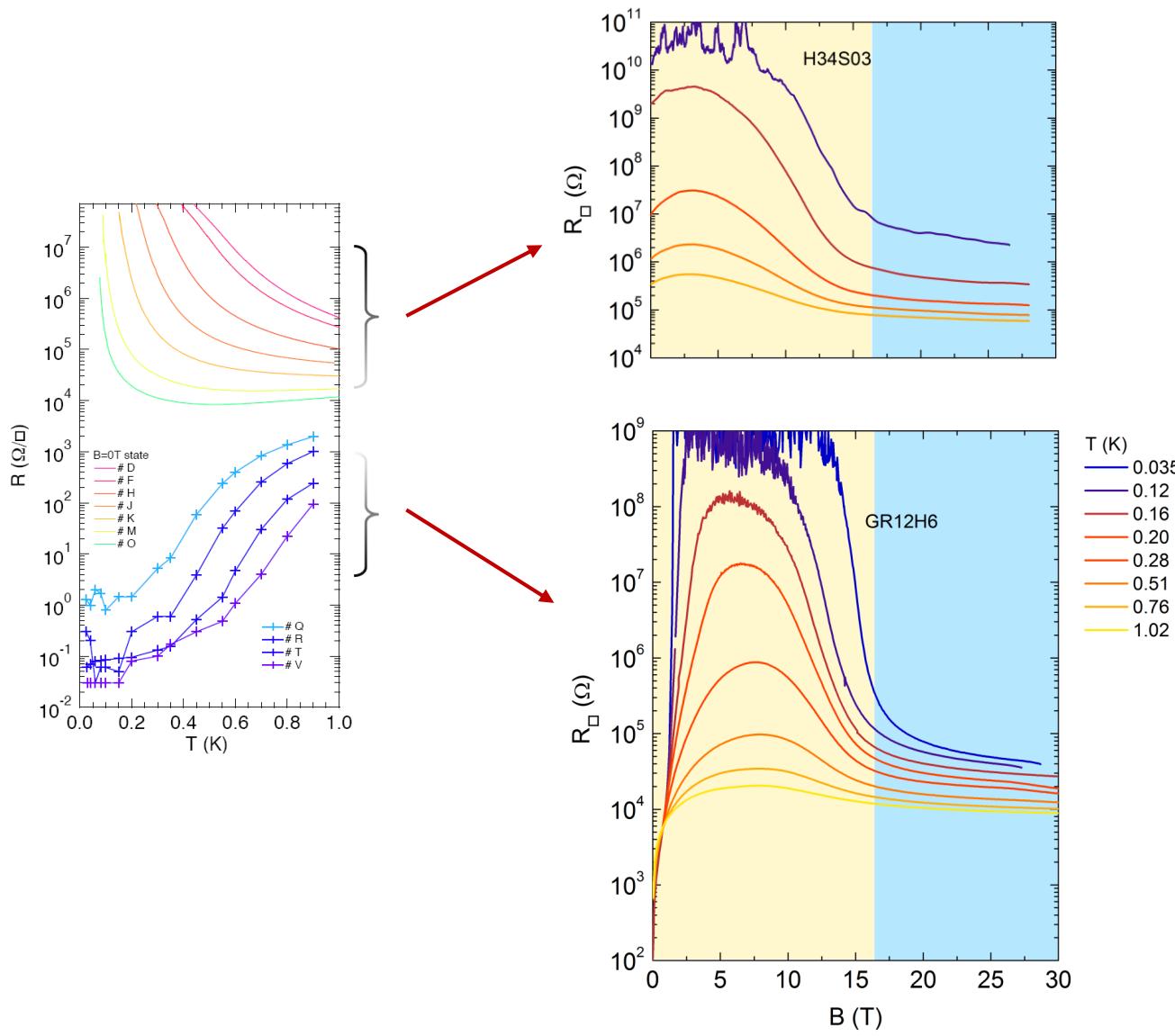
Water-cooled 35 T resistive magnet



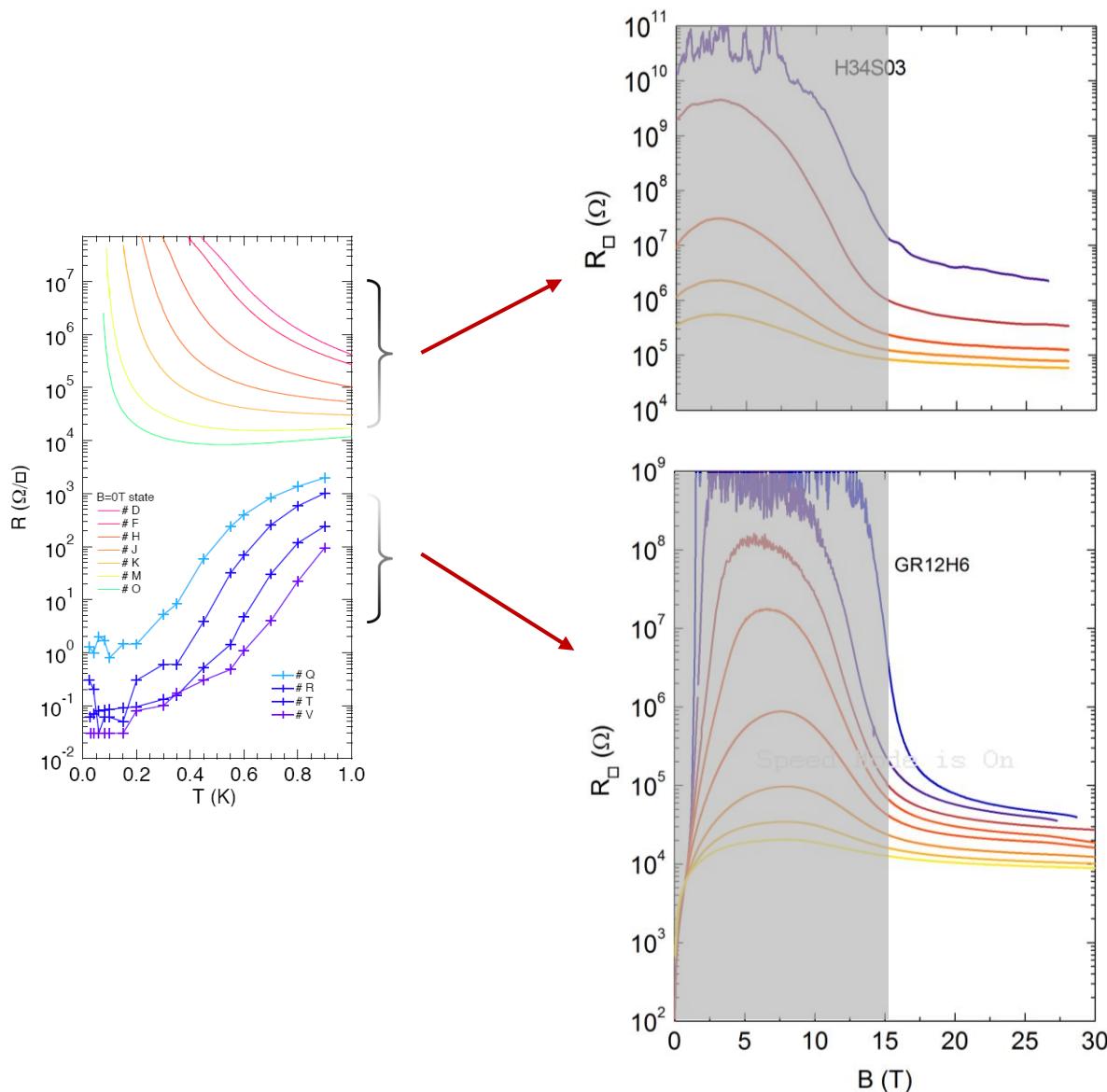
High-B termination of the magnetoresistance peak



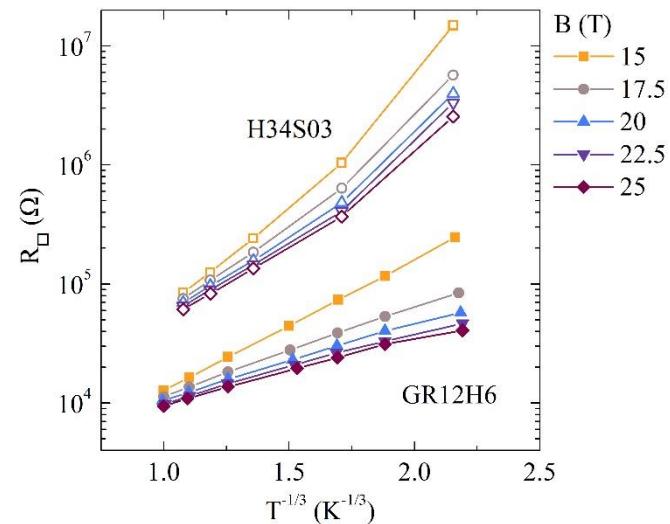
High-B termination of the magnetoresistance peak



High-B state: Fermionic insulator

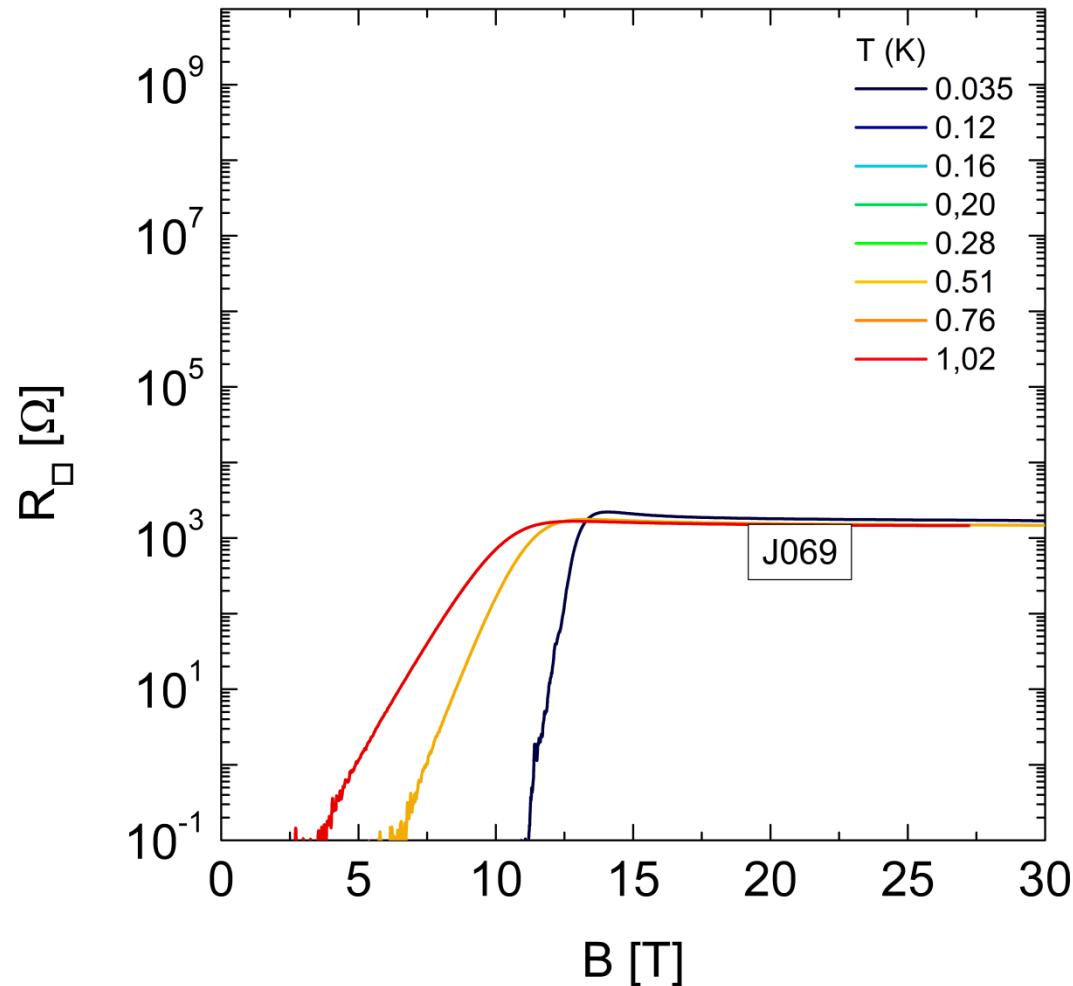


High field state :
Standard Mott hopping

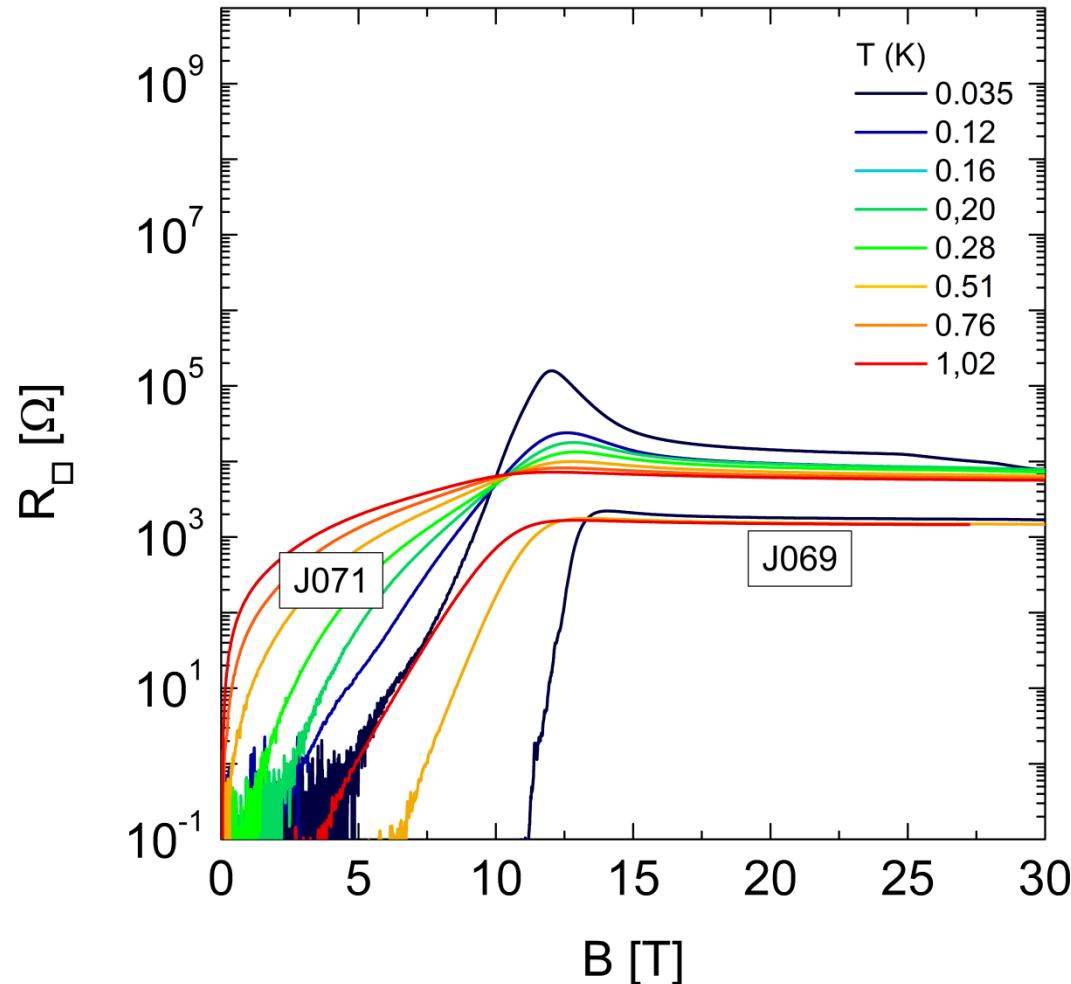


→ Fermionic insulator

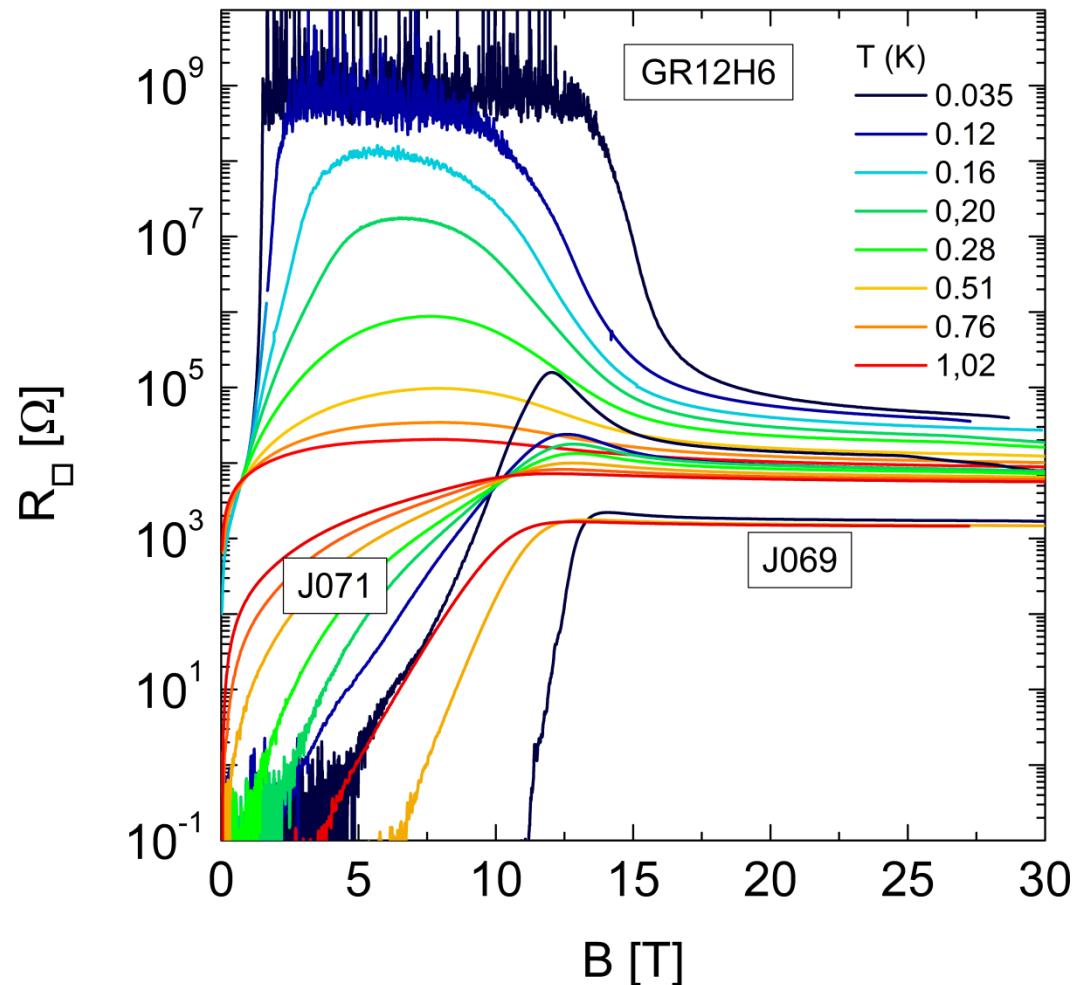
From superconductor to normal state



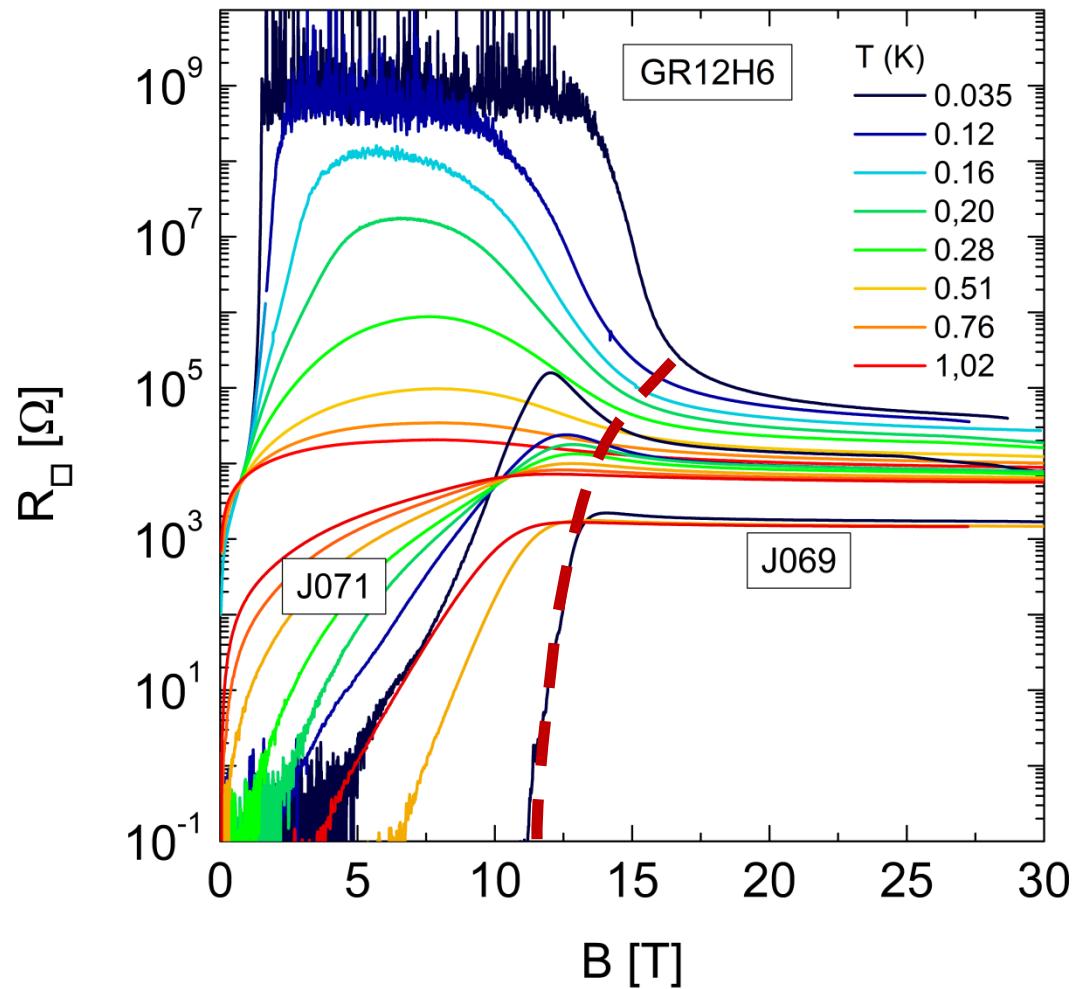
From superconductor to Cooper-pair insulator



From superconductor to Cooper-pair insulator

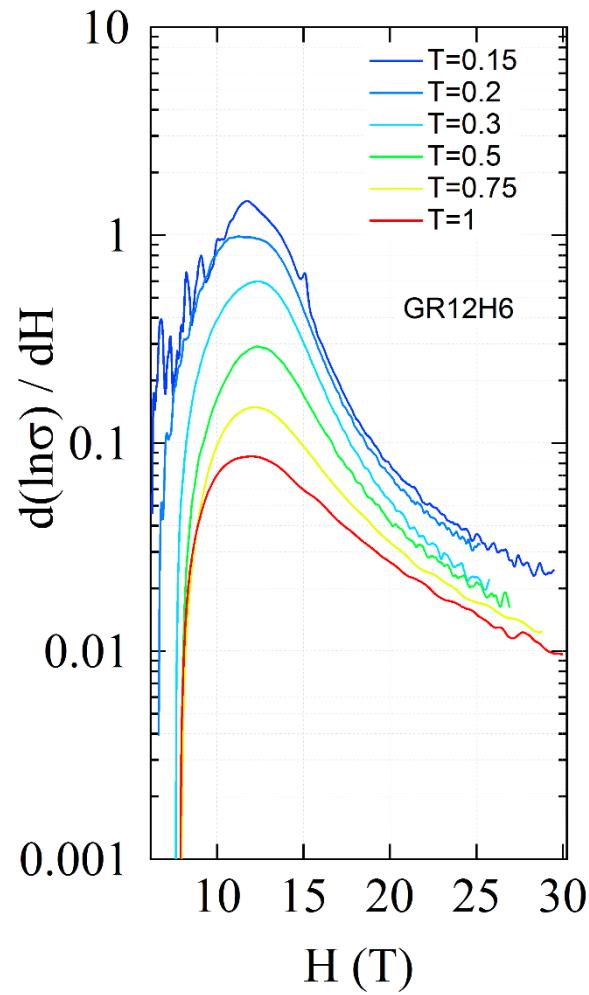
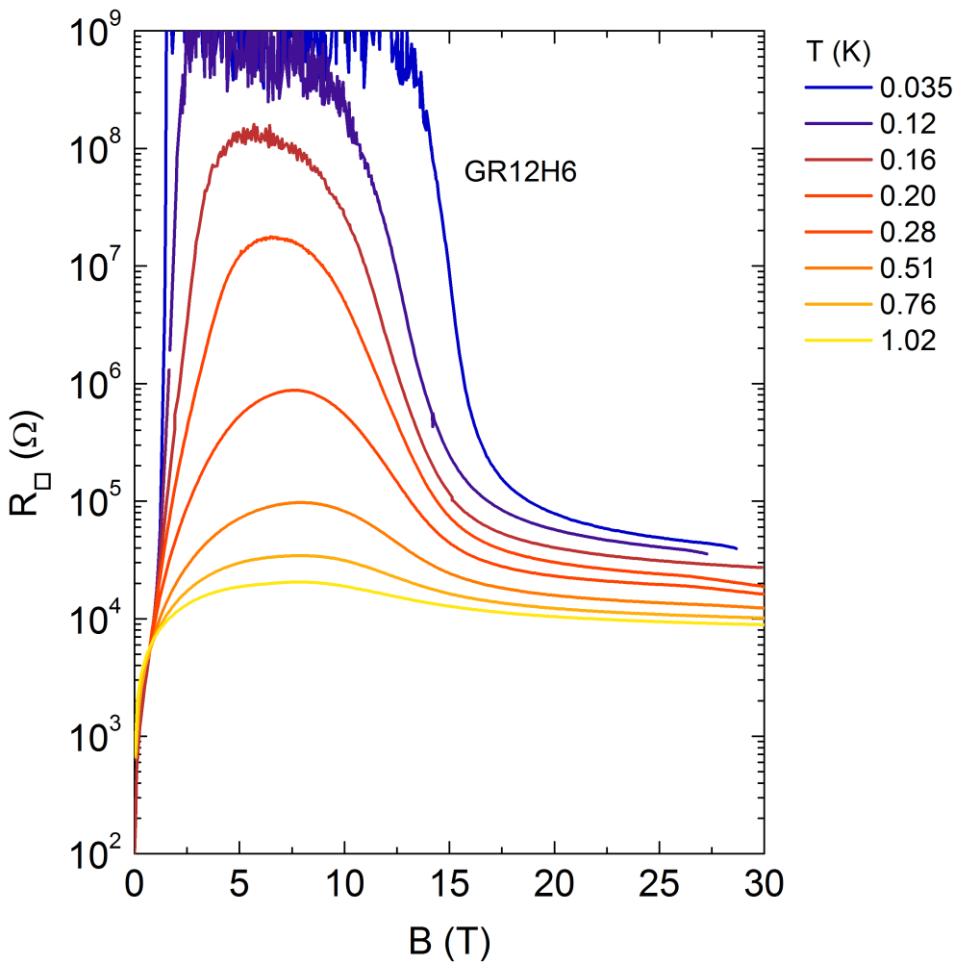


From superconductor to Cooper-pair insulator

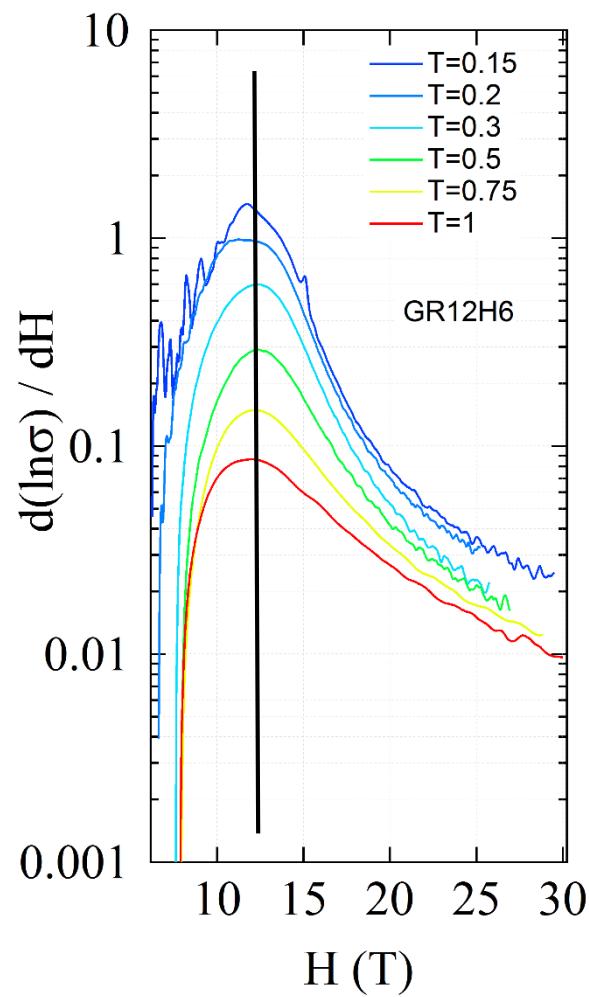
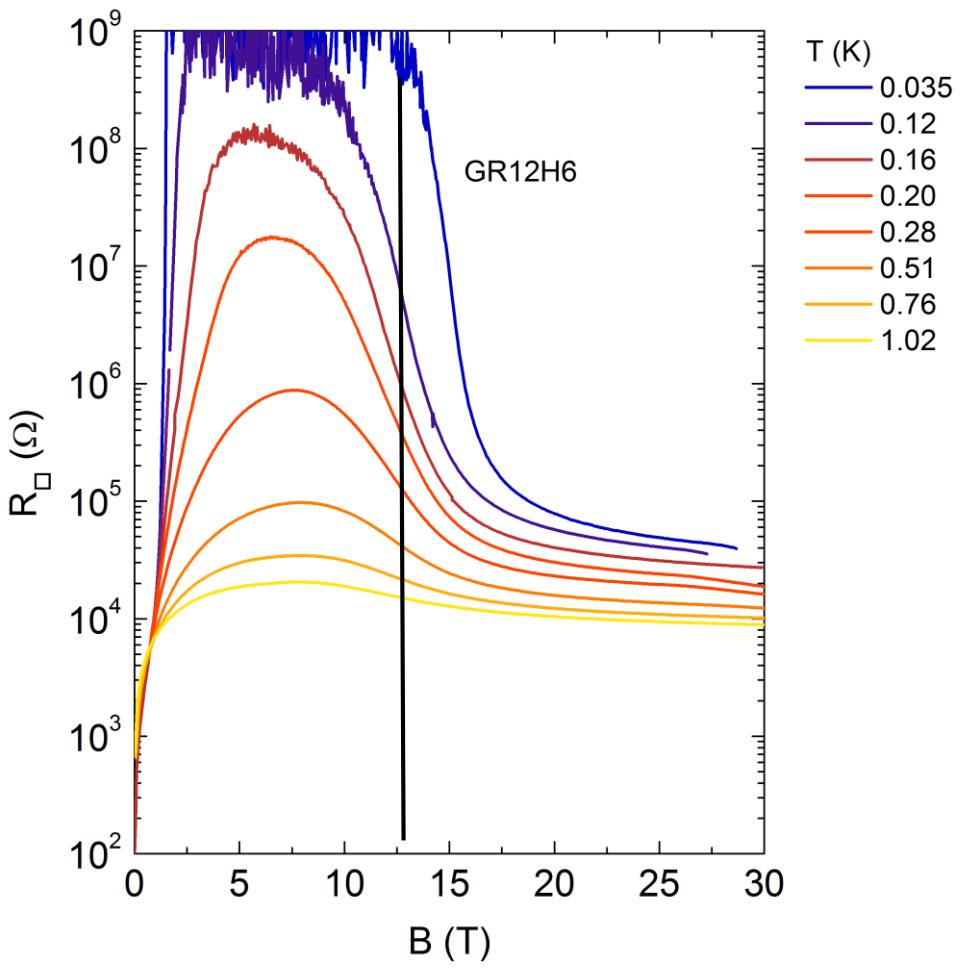


$H_c2(0)$ in low disorder samples coincides with
Cooper-pair to fermionic insulator transition

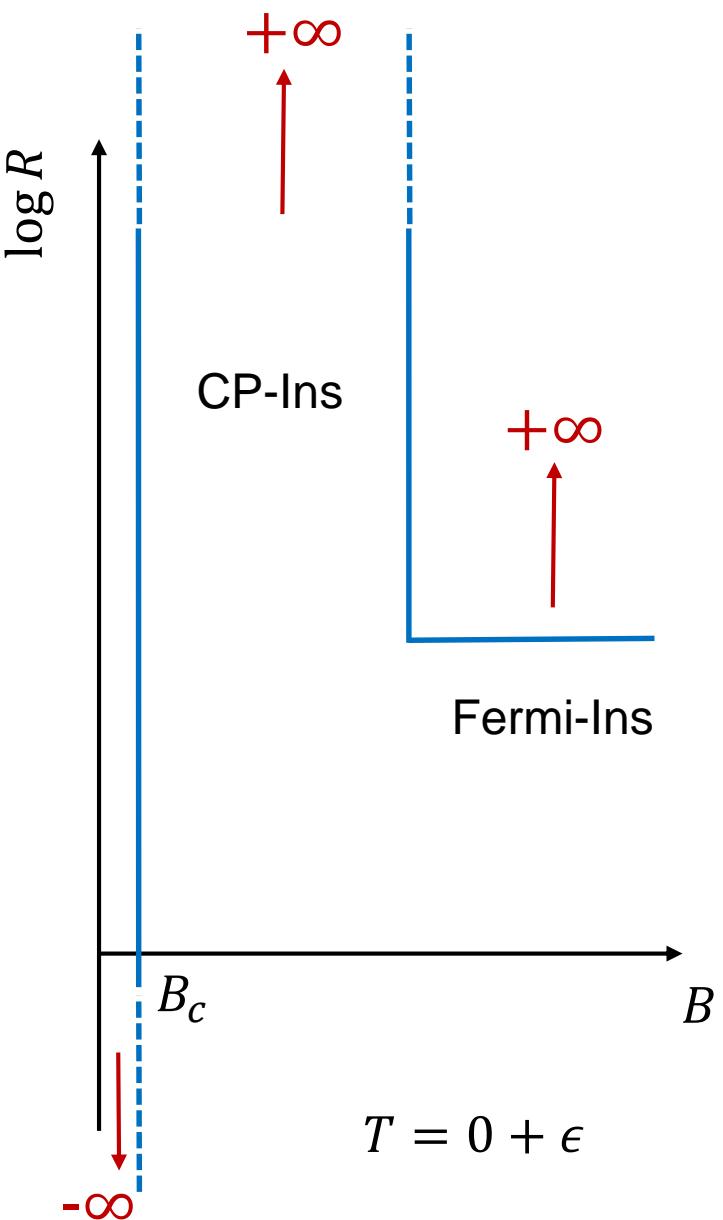
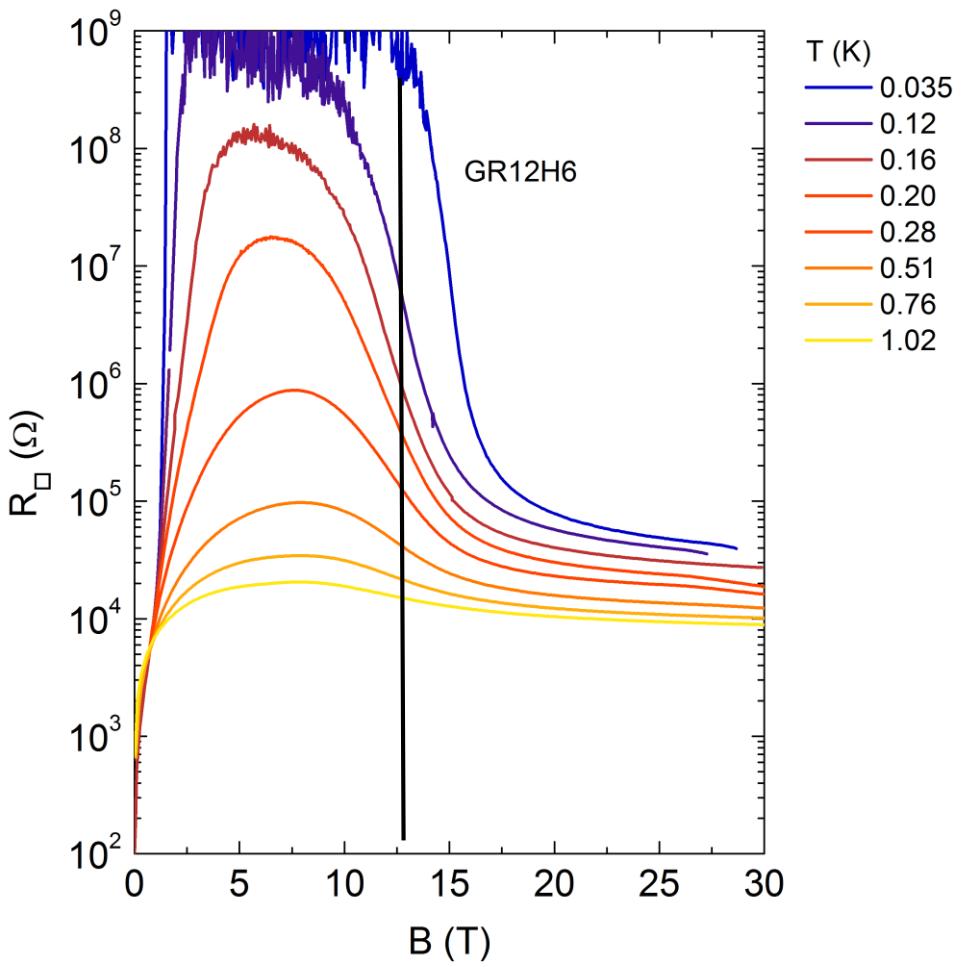
Insulator-to-insulator transition ?



Insulator-to-insulator transition ?



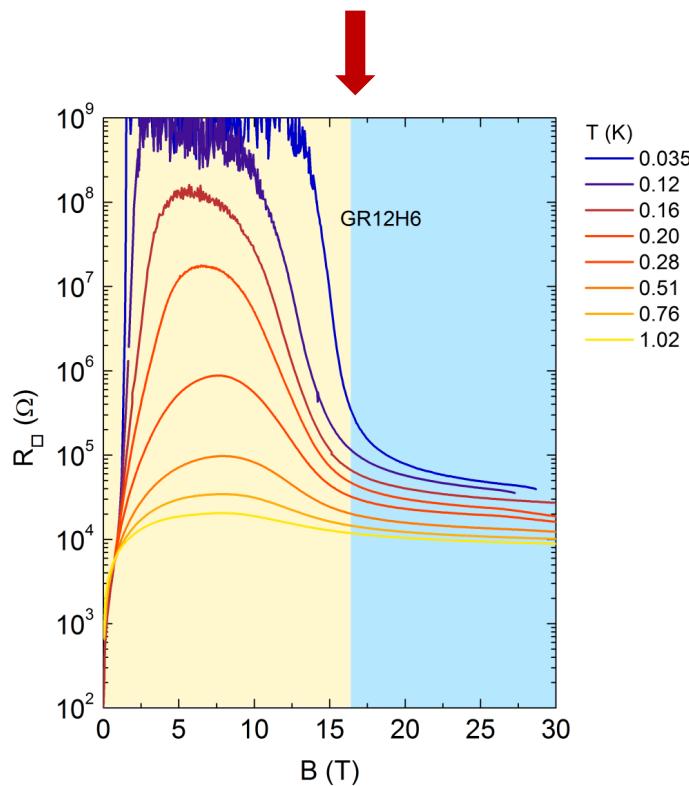
Insulator-to-insulator transition ?



High-B termination of the magnetoresistance peak

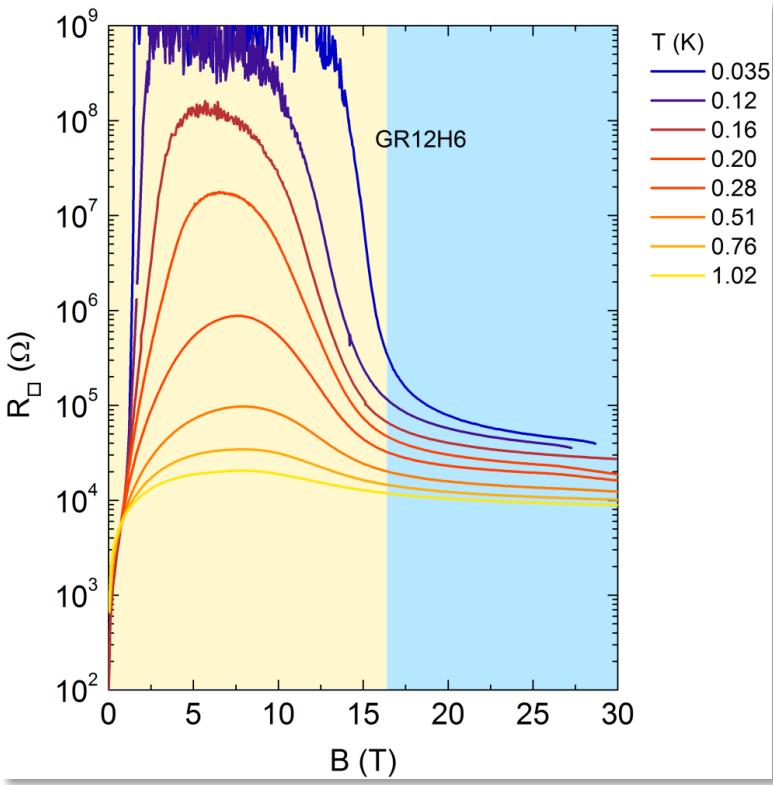
Cooper-pair insulator | fermionic insulator

$B \sim 15 T$



New insulator-to-insulator quantum phase transition or crossover ?

Conclusions



Low disorder films:

- $H_{c2}(0) \sim 12 - 15 T$
- $\xi_s \sim 4 \text{ nm} \Rightarrow 3D \text{ SC state}$
- No Pauli limit due to SOI

High disorder films

- VRH in the high-B state
- Bose insulator to Fermi insulator transition/crossover